DLP230NP および DLP230NPSE .23 1080P デジタル・マイクロミラー・デバイス

1 特長

- 超小型 0.23 インチ (5.95mm) 対角マイクロミラー アレイ
  - 画面に 1920 × 1080 ピクセルを表示
  - 5.4µm のマイクロミラー ピッチ
  - マイクロミラー傾斜角 : 17° (水平面に対して)
  - 側面照明による最適な効率と光学エンジン サイズ
  - 偏波無依存のアルミニウム製マイクロミラー表面
- 8 ビット SubLVDS 入力データ バス
- ディスプレイ アプリケーション専用の DLPC34x6 コントローラ
- 専用の DLPA2000、DLPA2005、DLPA3000、または DLPA3005 PMIC/LED ドライバによる信頼性の高い動作

2 ディスプレイ アプリケーション

- DLP サイネージ
- モバイル プロジェクタ
- スマート スピーカ
- 仮想現実 (VR) および拡張現実 (AR) 用ヘッドセットおよび眼鏡
- モバイル アクセサリ
- スマート ホーム ディスプレイ
- ピコ プロジェクタ

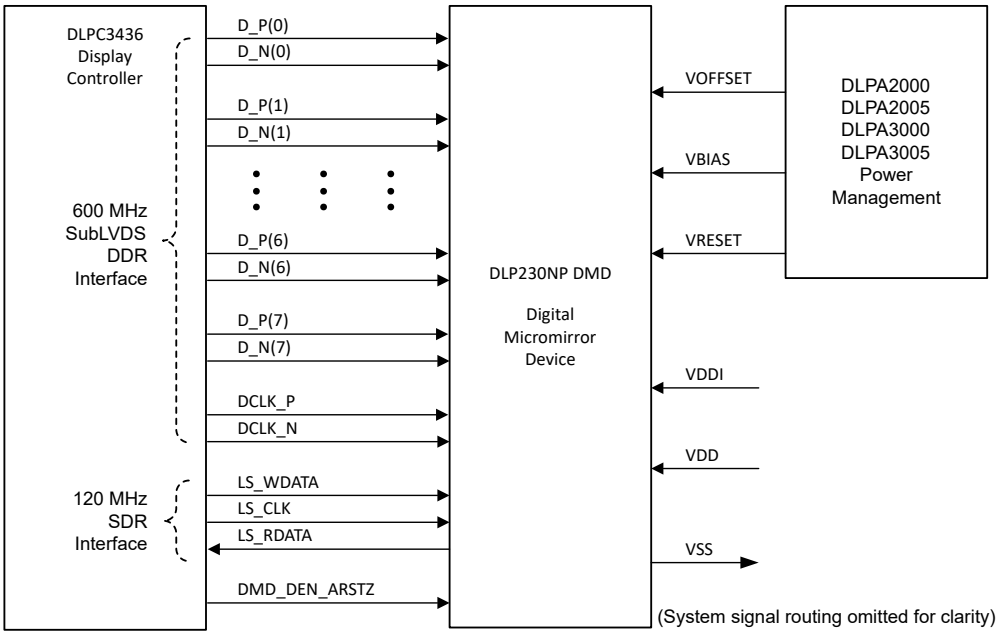
3 概要

DLP230NP および DLP230NPSE .23 1080p デジタル マイクロミラー デバイス (DMD) は、デジタル制御の MOEMS (micro-opto-electromechanical system) 空間光変調器 (SLM) です。適切な光学システムと組み合わせることにより、鮮明で高品質の 1080p 画像または映像を表示できます。最大輝度のチップセットは、DLP230NP DMD と DLPC3436 コントローラで構成されています。低輝度チップセットは、DLP230NPSE DMD と DLPC3436 コントローラで構成されています。DLPA3000 および DLPA3005 PMIC/LED ドライバは両方のチップセットをサポートし、DLPA2000 および DLPA2005 は最大輝度オプションのみをサポートします。このデバイスは物理的なサイズが小さいため、高画質、小さなフォーム ファクタ、低消費電力が重要な携帯機器に使用できます。

製品情報

部品番号	パッケージ(1)	パッケージ サイズ
DLP230NP	FQP (54)	16.8mm × 5.92mm × 3.58mm
DLP230NPSE		

(1) 利用可能なすべてのパッケージについては、データシートの末尾にある注文情報を参照してください。



アプリケーション概略図

このリソースの元の言語は英語です。翻訳は概要を便宜的に提供するもので、自動化ツール (機械翻訳) を使用していることがあり、TI では翻訳の正確性および妥当性につきましては一切保証いたしません。実際の設計などの前には、ti.com で必ず最新の英語版をご参照くださいますようお願いいたします。

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4 Pin Configuration and Functions

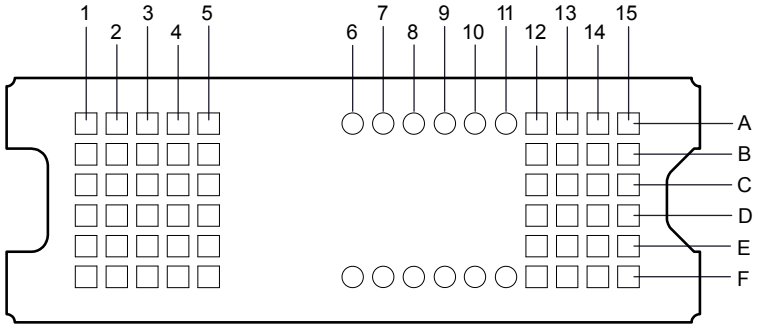


図 4-1. FQP Package, 54-Pin CLGA (Bottom View)

表 4-1. Pin Functions – Connector Pins

PIN[1]		TYPE	SIGNAL	DATA RATE	DESCRIPTION	PACKAGE NET LENGTH[2] (mm)
NAME	NO.					
DATA INPUTS						
D_N(0)	A2	I	SubLVDS	Double	Data, negative	1.96
D_N(1)	A1	I	SubLVDS	Double	Data, negative	1.42
D_N(2)	C1	I	SubLVDS	Double	Data, negative	1.35
D_N(3)	B4	I	SubLVDS	Double	Data, negative	3.36
D_N(4)	F5	I	SubLVDS	Double	Data, negative	4.29
D_N(5)	D4	I	SubLVDS	Double	Data, negative	3.20
D_N(6)	E1	I	SubLVDS	Double	Data, negative	1.76
D_N(7)	F3	I	SubLVDS	Double	Data, negative	2.66
D_P(0)	A3	I	SubLVDS	Double	Data, positive	1.97
D_P(1)	B1	I	SubLVDS	Double	Data, positive	1.49
D_P(2)	C2	I	SubLVDS	Double	Data, positive	1.44
D_P(3)	A4	I	SubLVDS	Double	Data, positive	3.45
D_P(4)	E5	I	SubLVDS	Double	Data, positive	4.32
D_P(5)	D5	I	SubLVDS	Double	Data, positive	3.27
D_P(6)	E2	I	SubLVDS	Double	Data, positive	1.85
D_P(7)	F2	I	SubLVDS	Double	Data, positive	2.75
DCLK_N	C3	I	SubLVDS	Double	Clock, negative	1.94
DCLK_P	D3	I	SubLVDS	Double	Clock, positive	2.02
CONTROL INPUTS						
LS_WDATA	A12	I	LPSDR[1]	Single	Write data for low speed interface	2.16
LS_CLK	B12	I	LPSDR	Single	Clock for low-speed interface	3.38
DMD_DEN_ARSTZ	B14	I	LPSDR	Single	Asynchronous reset DMD signal. A low signal places the DMD in reset. A high signal releases the DMD from reset and places it in active mode.	0.67
DMD_DEN_ARSTZ	F1	I	LPSDR	Single		14.90
LS_RDATA	C13	O	LPSDR	Single	Read data for low-speed interface	2.44
POWER						
V_{BIAS} [3]	A15	Power			Supply voltage for positive bias level at micromirrors	
V_{BIAS} [3]	A5	Power				

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表 4-1. Pin Functions – Connector Pins (続き)

PIN[1]		TYPE	SIGNAL	DATA RATE	DESCRIPTION	PACKAGE NET LENGTH[2] (mm)
NAME	NO.					
V_{OFFSET} [3]	F13	Power			Supply voltage for HVCMOS core logic. Supply voltage for stepped high level at micromirror address electrodes. Supply voltage for offset level at micromirrors	
V_{OFFSET} [3]	F4	Power				
V_{RESET}	B15	Power			Supply voltage for negative reset level at micromirrors	
V_{RESET}	B5	Power				
V_{DD} [3]	C15	Power			Supply voltage for LVCMOS core logic. Supply voltage for LPSDR inputs. Supply voltage for normal high level at micromirror address electrodes	
V_{DD}	C5	Power				
V_{DD}	D14	Power				
V_{DD}	D15	Power				
V_{DD}	E14	Power				
V_{DD}	E15	Power				
V_{DD}	F14	Power				
V_{DD}	F15	Power				
V_{DDI}	C14	Power			Supply voltage for SubLVDS receivers	
V_{DDI}	C4	Power				
V_{DDI}	D13	Power				
V_{DDI}	E13	Power				
V_{SS}	A13	Ground			Common return. Ground for all power	
V_{SS}	A14	Ground				
V_{SS}	B13	Ground				
V_{SS}	B2	Ground				
V_{SS}	B3	Ground				
V_{SS}	C12	Ground				
V_{SS}	D1	Ground				
V_{SS}	D12	Ground				
V_{SS}	D2	Ground				
V_{SS}	E12	Ground				
V_{SS}	E3	Ground				
V_{SS}	E4	Ground				
V_{SS}	F12	Ground				

(1) Low-speed interface is LPSDR and adheres to the Electrical Characteristics and AC/DC Operating Conditions table in JEDEC Standard No. 209B, *Low Power Double Data Rate (LPDDR)*. See JESD209B.
(2) Net trace lengths inside the package:
Relative dielectric constant for the FQP ceramic package is 9.8.
Propagation speed = 11.8 / sqrt (9.8) = 3.769in/ns.
Propagation delay = 0.265ns/inch = 265ps/in = 10.43ps/mm
(3) The following power supplies are all required to operate the DMD: V_{DD}, V_{DDI}, V_{OFFSET}, V_{BIAS}, V_{RESET}. All V_{SS} connections are also required.

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表 4-2. Pin Functions—Test Pads

NUMBER	SYSTEM BOARD
A6	Do not connect.
A7	Do not connect.
A8	Do not connect.
A9	Do not connect.
A10	Do not connect.
A11	Do not connect.
F6	Do not connect.
F7	Do not connect.
F8	Do not connect.
F9	Do not connect.
F10	Do not connect.
F11	Do not connect.

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5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted[1])

			MIN	MAX	UNIT
Supply voltage	V_{DD}	Supply voltage for LVCMOS core logic[2] Supply voltage for LPSDR low speed interface	–0.5	2.3	V
	V_{DDI}	Supply voltage for SubLVDS receivers[2]	–0.5	2.3	V
	V_{OFFSET}	Supply voltage for HVCMOS and micromirror electrode[2] [3]	–0.5	11	V
	V_{BIAS}	Supply voltage for micromirror electrode[2]	–0.5	19	V
	V_{RESET}	Supply voltage for micromirror electrode[2]	–15	0.5	V
	$\lvert V_{DDI}–V_{DD}\rvert$	Supply voltage delta (absolute value)[4]		0.3	V
	$\lvert V_{BIAS}–V_{OFFSET}\rvert$	Supply voltage delta (absolute value)[5]		11	V
	$\lvert V_{BIAS}–V_{RESET}\rvert$	Supply voltage delta (absolute value)[6]		34	V
Input voltage	Input voltage for other inputs LPSDR[2]		–0.5	V_{DD} + 0.5	V
	Input voltage for other inputs SubLVDS[2] [7]		–0.5	V_{DDI} + 0.5	V
Input pins	$\lvert V_{ID}\rvert$	SubLVDS input differential voltage (absolute value)[7]		810	mV
	I_{ID}	SubLVDS input differential current		10	mA
Clock frequency	f_{clock}	Clock frequency for low speed interface LS_CLK		130	MHz
	f_{clock}	Clock frequency for high speed interface DCLK		620	MHz
Environmental	T_{ARRAY} and T_{WINDOW}	Temperature – operational [8]	–20	90	°C
		Temperature – non-operational[8]	–40	90	°C
	$\lvert T_{DELTA}\rvert$	Absolute temperature delta between any point on the window edge and the ceramic test point TP1[9]		30	°C
	T_{DP}	Dew Point - operating and non-operating		81	°C

(1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
(2) All voltage values are with respect to the ground terminals (V_{SS}). The following power supplies are all required to operate the DMD: V_{DD}, V_{DDI}, V_{OFFSET}, V_{BIAS}, and V_{RESET}. All V_{SS} connections are also required.
(3) V_{OFFSET} supply transients must fall within specified voltages.
(4) Exceeding the recommended allowable absolute voltage difference between V_{DDI} and V_{DD} may result in excessive current draw.
(5) Exceeding the recommended allowable absolute voltage difference between V_{BIAS} and V_{OFFSET} may result in excessive current draw.
(6) Exceeding the recommended allowable absolute voltage difference between V_{BIAS} and V_{RESET} may result in excessive current draw.
(7) This maximum input voltage rating applies when each input of a differential pair is at the same voltage potential. SubLVDS differential inputs must not exceed the specified limit or damage may result to the internal termination resistors.
(8) The highest temperature of the active array (as calculated in セクション 6.6) or of any point along the window edge is defined in 図 6-1. The location of thermal test point TP2 in 図 6-1 is intended to measure the highest window edge temperature. If a particular application causes another point on the window edge to be at a higher temperature, that point should be used.
(9) Temperature delta is the highest difference between the ceramic test point 1 (TP1) and anywhere on the window edge as shown in 図 6-1. The window test point TP2 shown in 図 6-1 is intended to result in the worst case delta. If a particular application causes another point on the window edge to result in a larger delta temperature, that point should be used.

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5.2 Storage Conditions

Applicable for the DMD as a component or non-operating in a system.

		MIN	MAX	UNIT
T_{DMD}	DMD storage temperature	–40	85	°C
T_{DP}	Average dew point temperature (non-condensing) (1)		24	°C
T_{DP-ELR}	Elevated dew point temperature range (non-condensing) (2)	28	36	°C
CT_{ELR}	Cumulative time in elevated dew point temperature range		6	months

(1) The average over time (including storage and operating) that the device is not in the elevated dew point temperature range.
(2) Exposure to dew point temperatures in the elevated range during storage and operation should be limited to less than a total cumulative time of CT_{ELR}.

5.3 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

5.4 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted)(1) (2)

		MIN	NOM	MAX	UNIT
SUPPLY VOLTAGE RANGE(3)					
V_{DD}	Supply voltage for LVCMOS core logic Supply voltage for LPSDR low-speed interface	1.65	1.8	1.95	V
V_{DDI}	Supply voltage for SubLVDS receivers	1.65	1.8	1.95	V
V_{OFFSET}	Supply voltage for HVCMOS and micromirror electrode(4)	9.5	10	10.5	V
V_{BIAS}	Supply voltage for mirror electrode	17.5	18	18.5	V
V_{RESET}	Supply voltage for micromirror electrode	–14.5	–14	–13.5	V
$\lvert V_{DDI}–V_{DD}\rvert$	Supply voltage delta (absolute value)(5)			0.3	V
$\lvert V_{BIAS}–V_{OFFSET}\rvert$	Supply voltage delta (absolute value)(6)			10.5	V
$\lvert V_{BIAS}–V_{RESET}\rvert$	Supply voltage delta (absolute value)(7)			33	V
CLOCK FREQUENCY					
f_{clock}	Clock frequency for low speed interface LS_CLK(8)	108		120	MHz
f_{clock}	Clock frequency for high speed interface DCLK(9)	300		540	MHz
	Duty cycle distortion DCLK	44%		56%	
SUBLVDS INTERFACE(9)					
$\lvert V_{ID}\rvert$	SubLVDS input differential voltage (absolute value). See 図 5-8, 図 5-9.	150	250	350	mV
V_{CM}	Common mode voltage. See 図 5-8, 図 5-9.	700	900	1100	mV
$V_{SUBLVDS}$	SubLVDS voltage. See 図 5-8, 図 5-9.	575		1225	mV
Z_{LINE}	Line differential impedance (PWB/trace)	90	100	110	Ω
Z_{IN}	Internal differential termination resistance. See 図 5-10.	80	100	120	Ω
	100-Ω differential PCB trace	6.35		152.4	mm

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5.4 Recommended Operating Conditions (続き)

Over operating free-air temperature range (unless otherwise noted)(1) (2)

		MIN	NOM	MAX	UNIT
ENVIRONMENTAL					
T_{ARRAY}	Array temperature – long-term operational(10) (11) (12) (13)	0		40 to 70(12)	°C
	Array temperature – short-term operational, 25 hr max(11) (14)	–20		–10	°C
	Array temperature – short-term operational, 500 hr max(11) (14)	–10		0	°C
	Array temperature – short-term operational, 500 hr max(11) (14)	70		75	°C
T_{WINDOW}	Window temperature – operational(15) (16)			90	°C
$\lvert T_{DELTA} \rvert$	Absolute temperature difference between any point on the window edge and the ceramic test point TP1(17)			15	°C
T_{DP-AVG}	Average dew point temperature (non-condensing) (18)			24	°C
T_{DP-ELR}	Elevated dew point temperature range (non-condensing) (19)	28		36	°C
CT_{ELR}	Cumulative time in elevated dew point temperature range			6	months
ILLUMINATION					
ILL_{UV}	Illumination power at wavelengths < 410 nm(10)			10	mW/cm^2
ILL_{VIS}	Illumination power at wavelengths ≥ 410 nm and ≤ 800 nm(20)			26.1	W/cm^2
ILL_{IR}	Illumination power at wavelengths > 800 nm			10	mW/cm^2
ILL_{BLU}	Illumination power at wavelengths ≥ 410 nm and ≤ 475 nm(20)			8.3	W/cm^2
ILL_{BLU1}	Illumination power at wavelengths ≥ 410 nm and ≤ 445 nm(20)			1.5	W/cm^2
ILL_{θ}	Illumination marginal ray angle(15)			55	deg

(1) The functional performance of the device specified in this data sheet is achieved when operating the device within the limits defined by the *Recommended Operating Conditions*. No level of performance is implied when operating the device above or below the *Recommended Operating Conditions* limits.
(2) The following power supplies are all required to operate the DMD: V_{DD}, V_{DDI}, V_{OFFSET}, V_{BIAS}, and V_{RESET}. All V_{SS} connections are also required.
(3) All voltage values are with respect to the ground pins (V_{SS}).
(4) V_{OFFSET} supply transients must fall within specified max voltages.
(5) To prevent excess current, the supply voltage delta $|V_{DDI} – V_{DD}|$ must be less than the specified limit.
(6) To prevent excess current, the supply voltage delta $|V_{BIAS} – V_{OFFSET}|$ must be less than the specified limit.
(7) To prevent excess current, the supply voltage delta $|V_{BIAS} – V_{RESET}|$ must be less than the specified limit.
(8) LS_CLK must run as specified to ensure internal DMD timing for reset waveform commands.
(9) Refer to the SubLVDS timing requirements in セクション 5.7.
(10) Simultaneous exposure of the DMD to the maximum *Recommended Operating Conditions* for temperature and UV illumination will reduce device lifetime.
(11) The array temperature cannot be measured directly and must be computed analytically from the temperature measured at test point 1 (TP1) shown in 図 6-1 and the package thermal resistance using the calculation in セクション 6.6.
(12) Per 図 5-1, the maximum operational array temperature should be derated based on the micromirror landed duty cycle that the DMD experiences in the end application. Refer to セクション 6.8 for a definition of micromirror landed duty cycle.
(13) Long-term is defined as the usable life of the device.
(14) Short-term is the total cumulative time over the useful life of the device.
(15) The maximum marginal ray angle of the incoming illumination light at any point in the micromirror array, including at the pond of micromirrors (POM), should not exceed 55 degrees from the normal to the device array plane. The device window aperture has not necessarily been designed to allow incoming light at higher maximum angles to pass to the micromirrors, and the device performance has not been tested nor qualified at angles exceeding this. Illumination light exceeding this angle outside the micromirror array (including POM) will contribute to thermal limitations described in this document and may negatively affect lifetime.
(16) Window temperature is the highest temperature on the window edge shown in 図 6-1. The location of thermal test point TP2 in 図 6-1 is intended to measure the highest window edge temperature. If a particular application causes another point on the window edge to be at a higher temperature, that point should be used.
(17) Temperature delta is the highest difference between the ceramic test point 1 (TP1) and anywhere on the window edge shown in 図 6-1. The window test point TP2 shown in 図 6-1 is intended to result in the worst case delta temperature. If a particular application causes another point on the window edge to result in a larger delta temperature, that point should be used.
(18) The average over time (including storage and operating) that the device is not in the 'elevated dew point temperature range'.
(19) Exposure to dew point temperatures in the elevated range during storage and operation should be limited to less than a total cumulative time of CT_{ELR}.
(20) The maximum allowable optical power incident on the DMD is limited by the maximum optical power density for each wavelength range specified and the micromirror array temperature (T_{ARRAY}).

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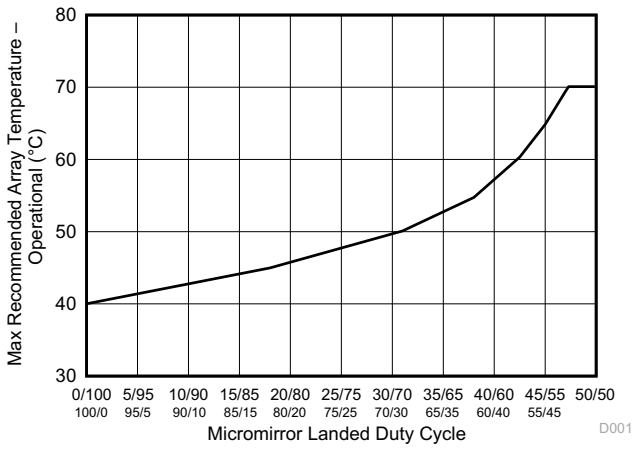


図 5-1. Maximum Recommended Array Temperature – Derating Curve

5.5 Thermal Information

THERMAL METRIC(1)		DLP230NP/NPSE FQP (CLGA) 54 PINS	UNIT
Thermal resistance	Active area to test point 1 (TP1) (1)	9.0	°C/W

(1) The DMD is designed to conduct absorbed and dissipated heat to the back of the package. The cooling system must be capable of maintaining the package within the temperature range specified in セクション 5.4. The total heat load on the DMD is largely driven by the incident light absorbed by the active area, although other contributions include light energy absorbed by the window aperture and electrical power dissipated by the array. Optical systems should be designed to minimize the light energy falling outside the window clear aperture since any additional thermal load in this area can significantly degrade the reliability of the device.

5.6 Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted)(1)

PARAMETER		TEST CONDITIONS(2)	MIN	TYP	MAX	UNIT
CURRENT						
I_{DD}	Supply current: V_{DD} (3) (4)	V_{DD} = 1.95 V			65	mA
		V_{DD} = 1.8 V		53		
I_{DDI}	Supply current: V_{DDI} (3) (4)	V_{DDI} = 1.95 V			12	mA
		V_{DD} = 1.8 V		11		
I_{OFFSET}	Supply current: V_{OFFSET} (5) (6)	V_{OFFSET} = 10.5 V			1.5	mA
		V_{OFFSET} = 10 V		1.4		
I_{BIAS}	Supply current: V_{BIAS} (5) (6)	V_{BIAS} = 18.5 V			0.3	mA
		V_{BIAS} = 18 V		0.29		
I_{RESET}	Supply current: V_{RESET} (6)	V_{RESET} = –14.5 V			–1.3	mA
		V_{RESET} = –14 V		–1.2		
POWER(7)						
P_{DD}	Supply power dissipation: V_{DD} (3) (4)	V_{DD} = 1.95 V			126.75	mW
		V_{DD} = 1.8 V		95.4		
P_{DDI}	Supply power dissipation: V_{DDI} (3) (4)	V_{DDI} = 1.95 V			23.4	mW
		V_{DD} = 1.8 V		19.8		
P_{OFFSET}	Supply power dissipation: V_{OFFSET} (5) (6)	V_{OFFSET} = 10.5 V			15.75	mW
		V_{OFFSET} = 10 V		14		

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5.6 Electrical Characteristics (続き)

Over operating free-air temperature range (unless otherwise noted)(1)

PARAMETER		TEST CONDITIONS(2)	MIN	TYP	MAX	UNIT
P_{BIAS}	Supply power dissipation: V_{BIAS} (5) (6)	V_{BIAS} = 18.5 V			5.55	mW
		V_{BIAS} = 18 V		5.22		
P_{RESET}	Supply power dissipation: V_{RESET} (6)	V_{RESET} = –14.5 V			18.85	mW
		V_{RESET} = –14 V		16.80		
P_{TOTAL}	Supply power dissipation: Total			151.22	190.3	mW
LPSDR INPUT(8)						
$V_{IH(DC)}$	DC input high voltage(9)		0.7 × V_{DD}		V_{DD} + 0.3	V
$V_{IL(DC)}$	DC input low voltage(9)		–0.3		0.3 × V_{DD}	V
$V_{IH(AC)}$	AC input high voltage(9)		0.8 × V_{DD}		V_{DD} + 0.3	V
$V_{IL(AC)}$	AC input low voltage(9)		–0.3		0.2 × V_{DD}	V
ΔV_T	Hysteresis ($V_{T+} – V_{T–}$)	図 5-10	0.1 × V_{DD}		0.4 × V_{DD}	V
I_{IL}	Low–level input current	V_{DD} = 1.95 V; V_I = 0 V	–100			nA
I_{IH}	High–level input current	V_{DD} = 1.95 V; V_I = 1.95 V			100	nA
LPSDR OUTPUT(10)						
V_{OH}	DC output high voltage	I_{OH} = –2 mA	0.8 × V_{DD}			V
V_{OL}	DC output low voltage	I_{OL} = 2 mA			0.2 × V_{DD}	V
CAPACITANCE						
C_{IN}	Input capacitance LPSDR	f = 1 MHz			10	pF
	Input capacitance SubLVDS	f = 1 MHz			20	pF
C_{OUT}	Output capacitance	f = 1 MHz			10	pF
C_{RESET}	Reset group capacitance	f = 1 MHz; (540 × 120) micromirrors	90		150	pF

(1) Device electrical characteristics are over *Recommended Operating Conditions* unless otherwise noted.
(2) All voltage values are with respect to the ground pins (V_{SS}).
(3) To prevent excess current, the supply voltage delta $|V_{DDI} – V_{DD}|$ must be less than the specified limit.
(4) Supply power dissipation based on non–compressed commands and data.
(5) To prevent excess current, the supply voltage delta $|V_{BIAS} – V_{OFFSET}|$ must be less than the specified limit.
(6) Supply power dissipation based on 3 global resets in 200 µs.
(7) The following power supplies are all required to operate the DMD: V_{DD}, V_{DDI}, V_{OFFSET}, V_{BIAS}, V_{RESET}. All V_{SS} connections are also required.
(8) LPSDR specifications are for pins LS_CLK and LS_WDATA.
(9) Low-speed interface is LPSDR and adheres to the Electrical Characteristics and AC/DC Operating Conditions table in JEDEC Standard No. 209B, *Low-Power Double Data Rate (LPDDR)* JESD209B.
(10) LPSDR specification is for pin LS_RDATA.

5.7 Timing Requirements

Device electrical characteristics are over *Recommended Operating Conditions* unless otherwise noted.

			MIN	NOM	MAX	UNIT
LPSDR						
t_r	Rise slew rate(1)	(30% to 80%) × V_{DD}, 図 5-3	1		3	V/ns
t_f	Fall slew rate(1)	(70% to 20%) × V_{DD}, 図 5-3	1		3	V/ns
t_r	Rise slew rate(2)	(20% to 80%) × V_{DD}, 図 5-3	0.25			V/ns
t_f	Fall slew rate(2)	(80% to 20%) × V_{DD}, 図 5-3	0.25			V/ns
t_c	Cycle time LS_CLK	図 5-2	7.7	8.3		ns
$t_{W(H)}$	Pulse duration LS_CLK high	50% to 50% reference points, 図 5-2	3.1			ns
$t_{W(L)}$	Pulse duration LS_CLK low	50% to 50% reference points, 図 5-2	3.1			ns

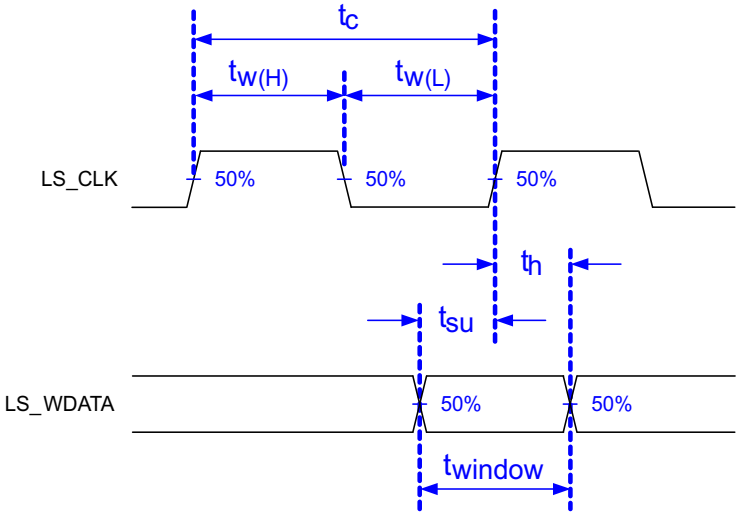
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5.7 Timing Requirements (続き)

Device electrical characteristics are over *Recommended Operating Conditions* unless otherwise noted.

			MIN	NOM	MAX	UNIT
t_{su}	Setup time	LS_WDATA valid before LS_CLK ↑, 図 5-2	1.5			ns
t_h	Hold time	LS_WDATA valid after LS_CLK ↑, 図 5-2	1.5			ns
t_{WINDOW}	Window time(1) (3)	Setup time + hold time, 図 5-2	3			ns
$t_{DERATING}$	Window time derating(1) (3)	For each 0.25 V/ns reduction in slew rate below 1 V/ns, 図 5-5		0.35		ns
SubLVDS						
t_r	Rise slew rate	20% to 80% reference points, 図 5-4	0.7	1		V/ns
t_f	Fall slew rate	80% to 20% reference points, 図 5-4	0.7	1		V/ns
t_c	Cycle time DCLK	図 5-6	1.79	1.85		ns
$t_{W(H)}$	Pulse duration DCLK high	50% to 50% reference points, 図 5-6	0.79			ns
$t_{W(L)}$	Pulse duration DCLK low	50% to 50% reference points, 図 5-6	0.79			ns
t_{su}	Setup time	D(0:7) valid before DCLK ↑ or DCLK ↓, 図 5-6				
t_h	Hold time	D(0:7) valid after DCLK ↑ or DCLK ↓, 図 5-6				
t_{WINDOW}	Window time	Setup time + hold time, 図 5-6, 図 5-7			0.3	ns
$t_{LVDS-ENABLE+REFGEN}$	Power-up receiver(4)				2000	ns

(1) Specification is for LS_CLK and LS_WDATA pins. Refer to LPSDR input rise slew rate and fall slew rate in 図 5-3.
(2) Specification is for DMD_DEN_ARSTZ pin. Refer to LPSDR input rise and fall slew rate in 図 5-3.
(3) Window time derating example: 0.5-V/ns slew rate increases the window time by 0.7 ns, from 3 to 3.7 ns.
(4) Specification is for SubLVDS receiver time only and does not take into account commanding and latency after commanding.



Low-speed interface is LPSDR and adheres to *セクション 5.6* and AC/DC Operating Conditions table in JEDEC Standard No. 209B, *Low Power Double Data Rate (LPDDR)* JESD209B.

図 5-2. LPSDR Switching Parameters

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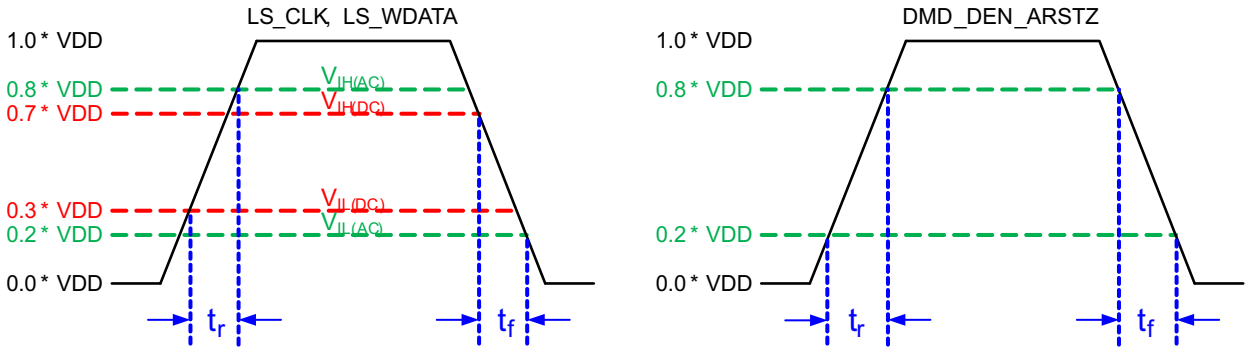


図 5-3. LPSDR Input Rise and Fall Slew Rate

Not to Scale

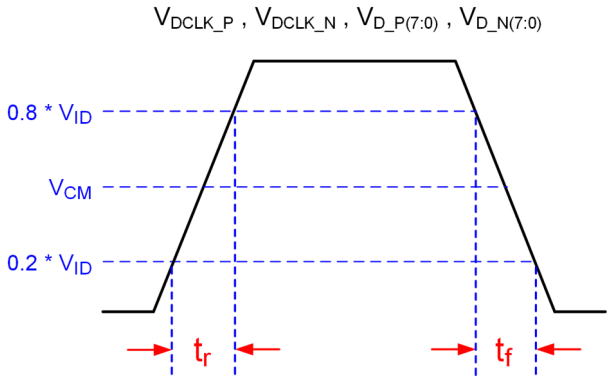


図 5-4. SubLVDS Input Rise and Fall Slew Rate

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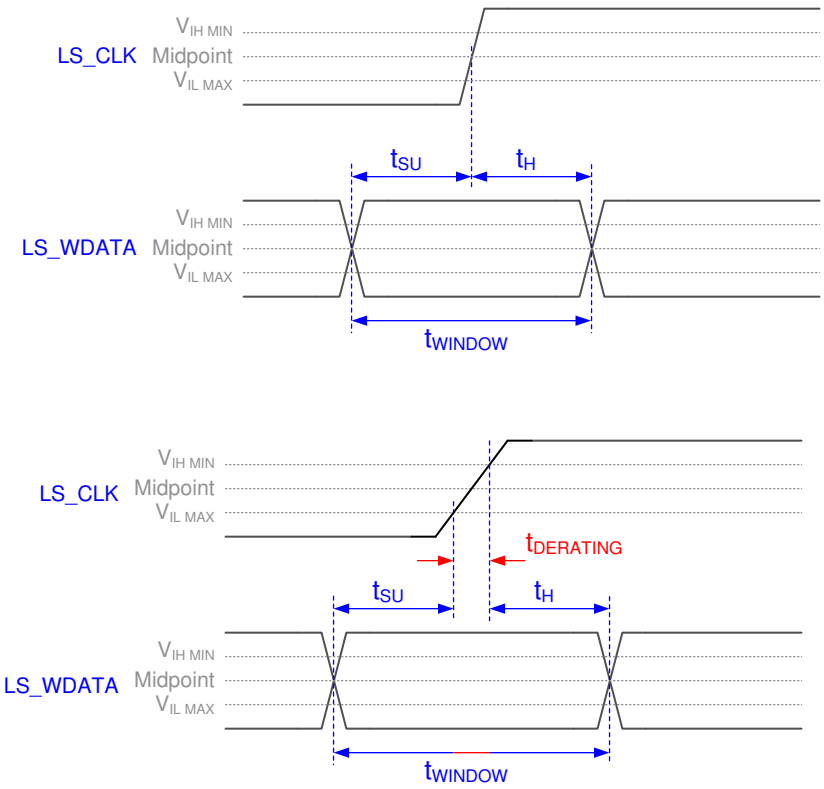


図 5-5. Window Time Derating Concept

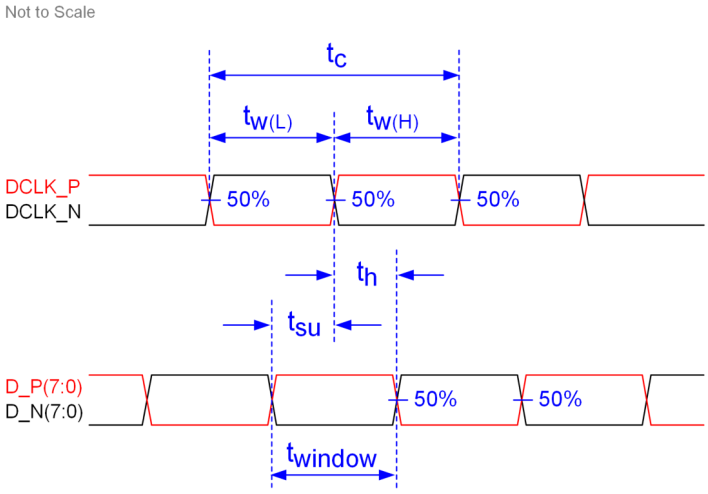
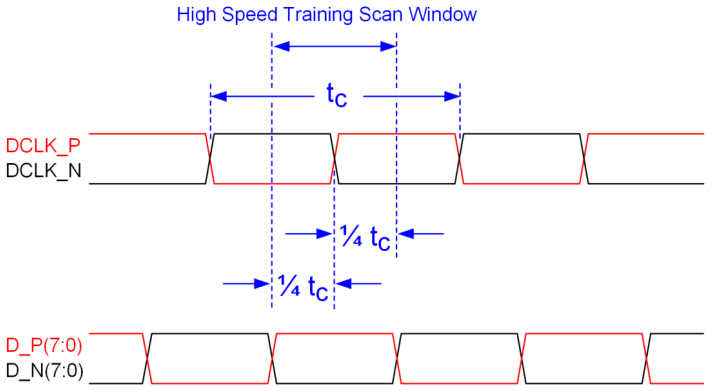


図 5-6. SubLVDS Switching Parameters



Note: Refer to セクション 6.3.3 for details.

図 5-7. High-Speed Training Scan Window

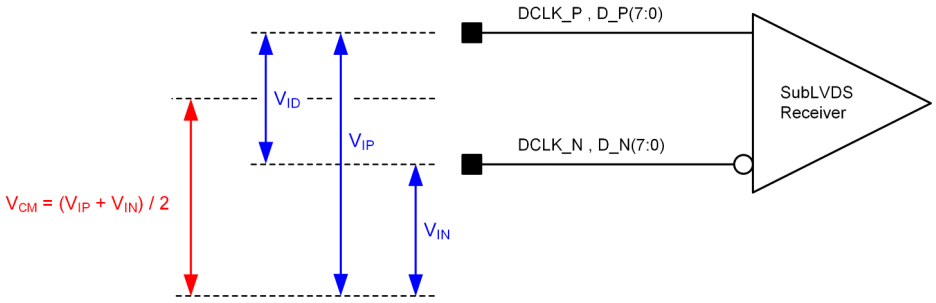


図 5-8. SubLVDS Voltage Parameters

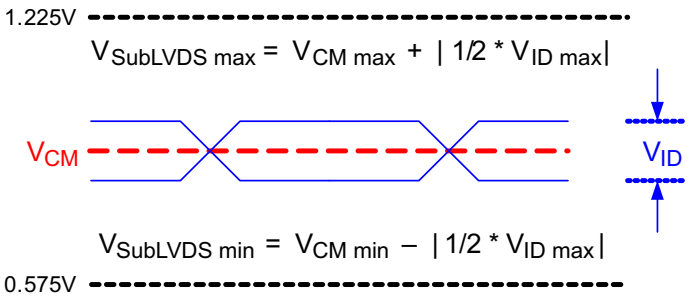


図 5-9. SubLVDS Waveform Parameters

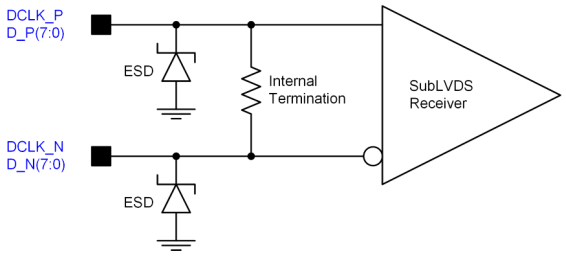


図 5-10. SubLVDS Equivalent Input Circuit

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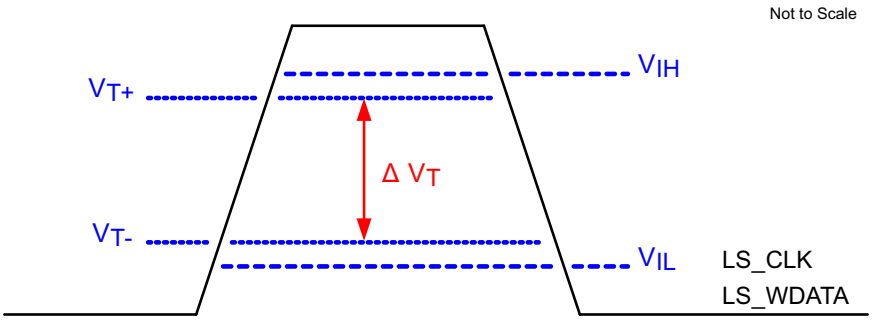


図 5-11. LPSDR Input Hysteresis

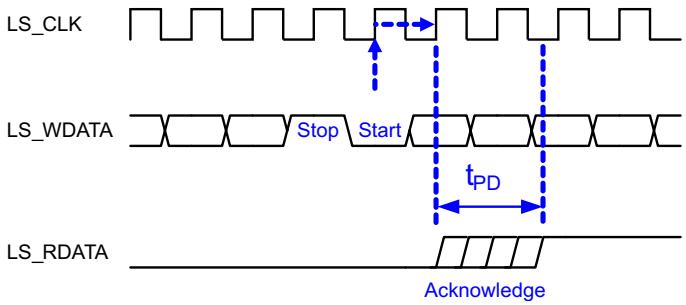
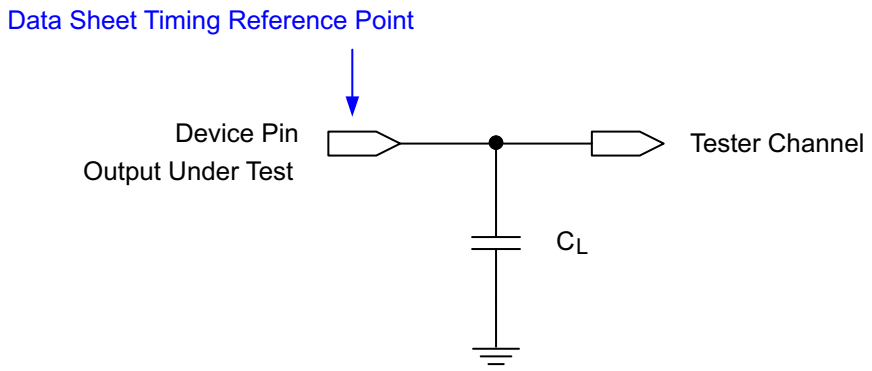


図 5-12. LPSDR Read Out



See セクション 6.3.4 for more information.

図 5-13. Test Load Circuit for Output Propagation Measurement

5.8 Switching Characteristics

Over operating free-air temperature range (unless otherwise noted). (1)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PD}	Output propagation, clock to Q, rising edge of LS_CLK input to LS_RDATA output. See 図 5-12.	C_L = 5 pF			11.1	ns
		C_L = 10 pF			11.3	ns
		C_L = 85 pF			15	ns
	Slew rate, LS_RDATA		0.5			V/ns
	Output duty cycle distortion, LS_RDATA		40%		60%	

(1) Device electrical characteristics comply with the values in セクション 5.4 unless otherwise noted.

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5.9 System Mounting Interface Loads

PARAMETER	MIN	NOM	MAX	UNIT
Maximum system mounting interface load to be applied to the:				
• Thermal interface area (1)			45	N
• Clamping and electrical interface area (1)			100	N

(1) Uniformly distributed within area shown in 図 5-14.

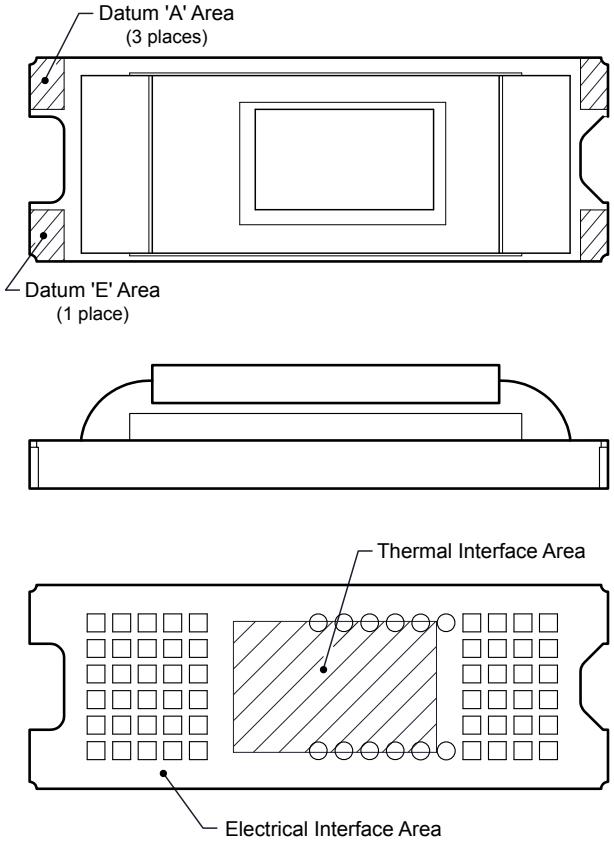


図 5-14. System Interface Loads

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5.10 Micromirror Array Physical Characteristics

PARAMETER		VALUE	UNIT
Number of active columns(1)	See 図 5-15.	960	micromirrors
Number of active rows(1)	See 図 5-15.	540	micromirrors
Micromirror (pixel) pitch	See 図 5-16.	5.4	µm
Micromirror active array width	Micromirror pitch × number of active columns; see 図 5-15	5.184	mm
Micromirror active array height	Micromirror pitch × number of active rows; see 図 5-15.	2.916	mm
Micromirror active border	Pond of micromirror (POM)(2)	20	micromirrors/side

(1) The fast switching speed of the DMD micromirrors combined with advanced DLP image processing algorithms enables each micromirror to display 4 distinct pixels on the screen during every frame, resulting in a full 1920 × 1080 pixel image being displayed.
(2) The structure and qualities of the border around the active array include a band of partially functional micromirrors called the POM. These micromirrors are structurally or electrically prevented from tilting toward the bright or ON state, but require an electrical bias to tilt toward OFF.

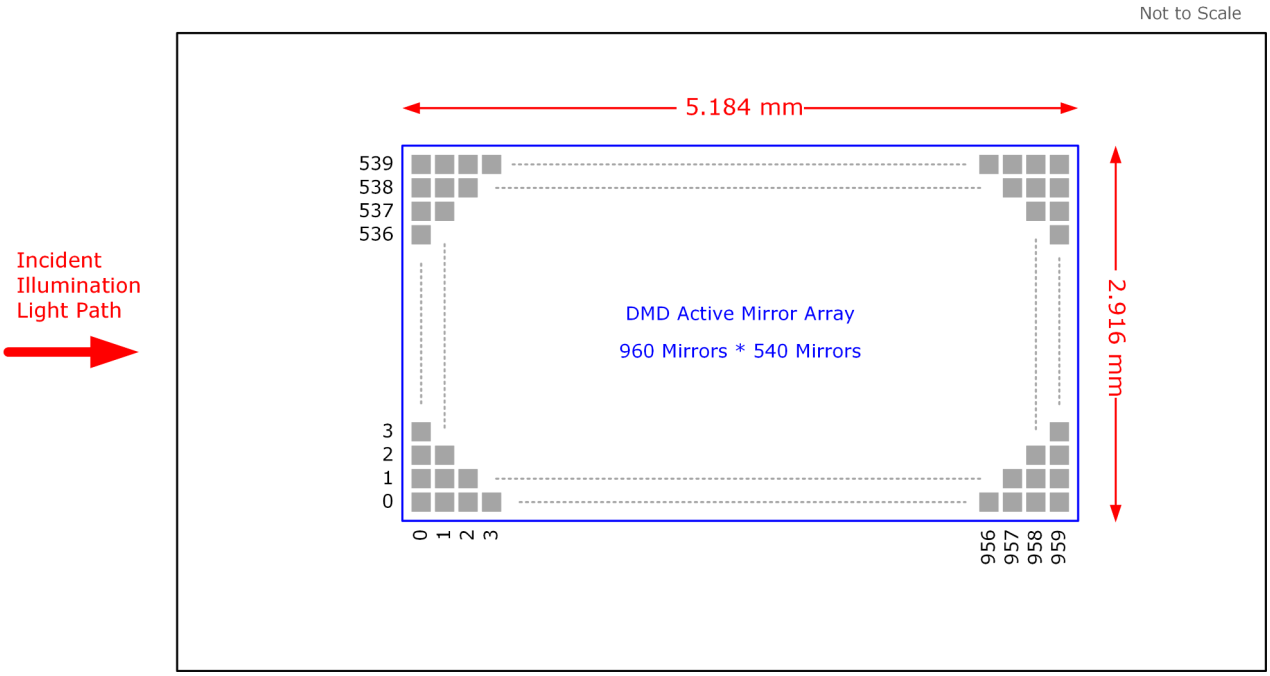


図 5-15. Micromirror Array Physical Characteristics

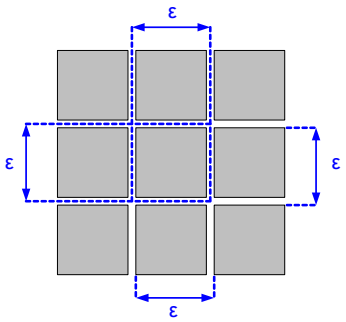


図 5-16. Mirror (Pixel) Pitch

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5.11 Micromirror Array Optical Characteristics

PARAMETER		TEST CONDITIONS	MIN	NOM	MAX	UNIT
Micromirror tilt angle		DMD landed state(1)		17		°
Micromirror tilt angle tolerance(2) (3) (4) (5)			–1.4		1.4	°
Micromirror tilt direction(6) (7)		Landed ON state		180		°
		Landed OFF state		270		
Micromirror crossover time(8)		Typical performance		1	3	µs
Micromirror switching time(9)		Typical performance	10			
Image performance(10)	Bright pixel(s) in active area (11)	Gray 10 screen (12)			0	micromirrors
	Bright pixel(s) in the POM (13)	Gray 10 screen (12)			1	
	Dark pixel(s) in the active area (14)	White screen			4	
	Adjacent pixel(s) (15)	Any screen			0	
	Unstable pixel(s) in active area (16)	Any screen			0	

(1) Measured relative to the plane formed by the overall micromirror array.
(2) Additional variation exists between the micromirror array and the package datums.
(3) Represents the landed tilt angle variation relative to the nominal landed tilt angle.
(4) Represents the variation that can occur between any two individual micromirrors, located on the same device or located on different devices.
(5) For some applications, it is critical to account for the micromirror tilt angle variation in the overall system optical design. With some system optical designs, the micromirror tilt angle variation within a device may result in perceivable non-uniformities in the light field reflected from the micromirror array. With some system optical designs, the micromirror tilt angle variation between devices may result in colorimetry variations, system efficiency variations or system contrast variations.
(6) When the micromirror array is landed (not parked), the tilt direction of each individual micromirror is dictated by the binary contents of the CMOS memory cell associated with each individual micromirror. A binary value of 1 results in a micromirror landing in the ON state direction. A binary value of 0 results in a micromirror landing in the OFF state direction. See 図 5-17.
(7) Micromirror tilt direction is measured as in a typical polar coordinate system: Measuring counter-clockwise from a 0° reference which is aligned with the +X Cartesian axis.
(8) The time required for a micromirror to nominally transition from one landed state to the opposite landed state.
(9) The minimum time between successive transitions of a micromirror
(10) Conditions of Acceptance: All DMD image quality returns will be evaluated using the following projected image test conditions:
Test set degamma shall be linear
Test set brightness and contrast shall be set to nominal
The diagonal size of the projected image shall be a minimum of 20 inches
The projections screen shall be 1X gain
The projected image shall be inspected from a 38-inch minimum viewing distance
The image shall be in focus during all image quality tests
(11) Bright pixel definition: A single pixel or mirror that is stuck in the ON position and is visibly brighter than the surrounding pixels
(12) Gray 10 screen definition: All areas of the screen are colored with the following settings:
Red = 10/255
Green = 10/255
Blue = 10/255
(13) POM definition: Rectangular border of off-state mirrors surrounding the active area
(14) Dark pixel definition: A single pixel or mirror that is stuck in the OFF position and is visibly darker than the surrounding pixels
(15) Adjacent pixel definition: Two or more stuck pixels sharing a common border or common point, also referred to as a cluster
(16) Unstable pixel definition: A single pixel or mirror that does not operate in sequence with parameters loaded into memory. The unstable pixel appears to be flickering asynchronously with the image.

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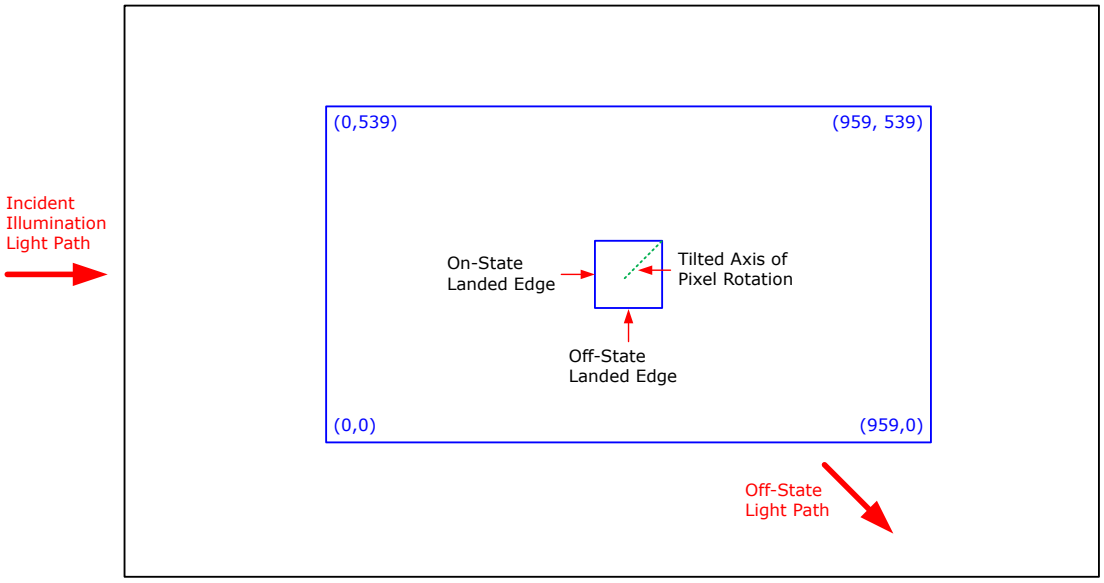


図 5-17. Landed Pixel Orientation and Tilt

5.12 Window Characteristics

PARAMETER(1)		MIN	NOM	MAX	UNIT
Window material designation			Corning Eagle XG		
Window refractive index	At wavelength 546.1 nm		1.5119		
Window aperture(2)				See (2)	
Illumination overfill(3)				See (3)	
Window transmittance, single-pass through both surfaces and glass	Minimum within the wavelength range 420 to 680 nm. Applies to all angles 0° to 30° AOI	97%			
	Average over the wavelength range 420 to 680 nm. Applies to all angles 30° to 45° AOI	97%			

(1) See セクション 6.5 for more information.
(2) See the package mechanical characteristics for details regarding the size and location of the window aperture.
(3) The active area of the device is surrounded by an aperture on the inside of the DMD window surface that masks structures of the DMD device assembly from normal view. The aperture is sized to anticipate several optical conditions. Overfill light illuminating the area outside the active array can scatter and create adverse effects to the performance of an end application using the DMD. The illumination optical system should be designed to limit light flux incident outside the active array to less than 10% of the average flux level in the active area. Depending on the particular system's optical architecture and assembly tolerances, the amount of overfill light on the outside of the active array may cause system performance degradation.

5.13 Chipset Component Usage Specification

注

TI assumes no responsibility for image quality artifacts or DMD failures caused by optical system operating conditions exceeding limits described previously.

The is a component of one or more DLP® chipsets. Reliable function and operation of the requires that it be used in conjunction with the other components of the applicable DLP chipset, including those components that contain or implement TI DMD control technology. TI DMD control technology consists of the TI technology and devices used for operating or controlling a DLP DMD.

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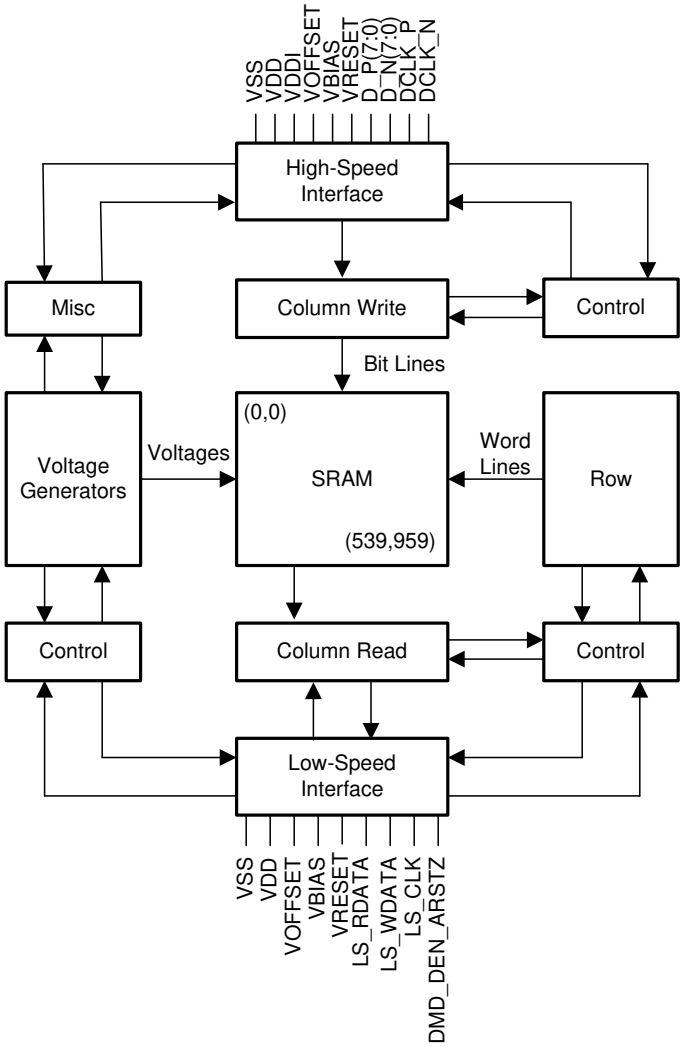
6 Detailed Description

6.1 Overview

The DLP230NP and DLP230NPSE devices are 0.23-inch diagonal spatial light modulators of aluminum micromirrors. The micromirror array size is 960 columns by 540 rows in a square micromirror arrangement. The fast switching speed of the DMD micromirrors, combined with advanced DLP image processing algorithms, enables each micromirror to display 4 distinct pixels on the screen during every frame, resulting in a full 1920 × 1080 pixel image display. The electrical interface is sub-low voltage differential signaling (SubLVDS) data.

For the DLP230NP device, the DLPA2000, DLPA2005, DLPA3000, and DLPA3005 PMIC/LED drivers support this chipset. Currently, only the DLPA3000 driver supports the DLP230NPSE DMD. To ensure reliable operation, the DLP230NP/NPSE DMD must always be used with the DLPC34x6 ZVB display controller and the DLPA2000, DLPA2005, DLPA3000, or DLPA3005 PMIC/LED driver.

6.2 Functional Block Diagram



A. Details are omitted for clarity.

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6.3 Feature Description

6.3.1 Power Interface

The power management IC DLPA2000, DLPA2005, DLPA3000 , and DLPA3005 contain three regulated DC supplies for the DMD reset circuitry: V_{BIAS}, V_{RESET} and V_{OFFSET}, as well as the two regulated DC supplies for the DLPC34x6ZVB controller.

6.3.2 Low-Speed Interface

The low speed interface handles instructions that configure the DMD and control reset operation. LS_CLK is the low–speed clock, and LS_WDATA is the low speed data input.

6.3.3 High-Speed Interface

The purpose of the high-speed interface is to transfer pixel data rapidly and efficiently, making use of high speed DDR transfer and compression techniques to save power and time. The high-speed interface is composed of differential SubLVDS receivers for inputs with a dedicated clock.

6.3.4 Timing

The data sheet provides timing at the device pin. For output timing analysis, the tester pin electronics and its transmission line effects must be taken into account. 図 5-13 shows an equivalent test load circuit for the output under test. Timing reference loads are not intended as a precise representation of any particular system environment or depiction of the actual load presented by a production test. System designers should use IBIS or other simulation tools to correlate the timing reference load to a system environment. The load capacitance value stated is only for characterization and measurement of AC timing signals. This load capacitance value does not indicate the maximum load the device is capable of driving.

6.4 Device Functional Modes

The DLPC34x6 controller manages the functional modes of the DMD. For more information, download the controller data sheet or contact a TI applications engineer.

6.5 Optical Interface and System Image Quality Considerations

TI assumes no responsibility for end-equipment optical performance. Achieving the desired end-equipment optical performance involves making trade-offs between numerous component and system design parameters. Optimizing system optical performance and image quality strongly relate to optical system design parameter trades. Although it is not possible to anticipate every conceivable application, projector image quality and optical performance is contingent on compliance to the optical system operating conditions described in the following sections.

6.5.1 Numerical Aperture and Stray Light Control

The angle defined by the numerical aperture of the illumination and projection optics at the DMD optical area should be the same. This angle should not exceed the nominal device mirror tilt angle unless appropriate apertures are added in the illumination and projection pupils to block out flat-state and stray light from the projection lens. The mirror tilt angle defines the DMD's capability to separate the ON optical path from any other light path, including undesirable flat–state specular reflections from the DMD window, DMD border structures, or other system surfaces near the DMD such as prism or lens surfaces. If the numerical aperture exceeds the mirror tilt angle, or if the projection numerical aperture angle is more than two degrees larger than the illumination numerical aperture angle, objectionable artifacts in the display’s border and active area could occur.

6.5.2 Pupil Match

TI’s optical and image quality specifications assume that the exit pupil of the illumination optics is nominally centered within 2° of the entrance pupil of the projection optics. Misalignment of pupils can create objectionable artifacts in the display’s border and/or active area, which may require additional system apertures to control, especially if the numerical aperture of the system exceeds the pixel tilt angle.

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6.5.3 Illumination Overfill

The active area of the device is surrounded by an aperture on the inside DMD window surface that masks structures of the DMD chip assembly from normal view and is sized to anticipate several optical operating conditions. Overfill light illuminating the window aperture can create artifacts from the edge of the window aperture opening and other surface anomalies that may be visible on the screen. The illumination optical system should be designed to limit light flux incident anywhere on the window aperture from exceeding approximately 10% of the average flux level in the active area. Depending on the particular system's optical architecture, overfill light may have to be further reduced below the suggested 10% level in order to be acceptable.

6.6 Micromirror Array Temperature Calculation

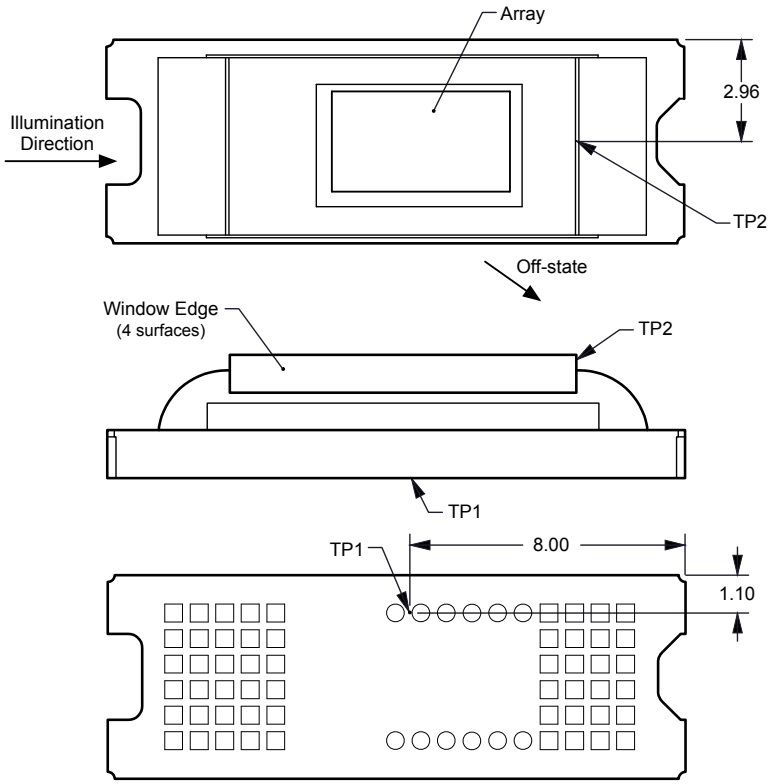


図 6-1. DMD Thermal Test Points

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Micromirror array temperature cannot be measured directly, therefore it must be computed analytically from measurement points on the outside of the package, the package thermal resistance, the electrical power, and the illumination heat load. The relationship between array temperature and the reference ceramic temperature (thermal test TP1 in 図 6-1) is provided by the following equations:

$$T_{ARRAY} = T_{CERAMIC} + (Q_{ARRAY} \times R_{ARRAY\text{-}TO\text{-}CERAMIC})$$

$$Q_{ARRAY} = Q_{ELECTRICAL} + Q_{ILLUMINATION}$$

where

- T_{ARRAY} = Computed array temperature (°C)
- $T_{CERAMIC}$ = Measured ceramic temperature (°C) (TP1 location)
- $R_{ARRAY\text{-}TO\text{-}CERAMIC}$ = Thermal resistance of package specified in セクション 5.5 from array to ceramic TP1 (°C/Watt)
- Q_{ARRAY} = Total DMD power on the array (W) (electrical + absorbed)
- $Q_{ELECTRICAL}$ = Nominal electrical power (W)
- $Q_{INCIDENT}$ = Incident illumination optical power (W)
- $Q_{ILLUMINATION}$ = (DMD average thermal absorptivity × $Q_{INCIDENT}$) (W)
- DMD average thermal absorptivity = 0.4

The electrical power dissipation of the DMD is variable and depends on the voltages, data rates, and operating frequencies. A nominal electrical power dissipation to use when calculating array temperature is 0.17 Watts. The absorbed power from the illumination source is variable and depends on the operating state of the micromirrors and the intensity of the light source. The equations shown above are valid for a single chip or multichip DMD system. It assumes an illumination distribution of 83.7% on the active array and 16.3% on the array border.

The sample calculation for a typical projection application is as follows:

$Q_{INCIDENT}$ = 2.9W (measured)

$T_{CERAMIC}$ = 55.0°C (measured)

$Q_{ELECTRICAL}$ = 0.17W

Q_{ARRAY} = 0.17W + (0.40 × 2.9 W) = 1.33W

T_{ARRAY} = 55.0°C + (1.33 W × 9.0°C/W) = 67.0°C

6.7 Micromirror Power Density Calculation

The calculation of the optical power density of the illumination on the DMD in the different wavelength bands uses the total measured optical power on the DMD, percent illumination overfill, area of the active array, and ratio of the spectrum in the wavelength band of interest to the total spectral optical power.

- $ILL_{UV} = [OP_{UV\text{-}RATIO} \times Q_{INCIDENT}] \times 1000 \div A_{ILL}$ (mW/cm^2)
- $ILL_{VIS} = [OP_{VIS\text{-}RATIO} \times Q_{INCIDENT}] \div A_{ILL}$ (W/cm^2)
- $ILL_{IR} = [OP_{IR\text{-}RATIO} \times Q_{INCIDENT}] \times 1000 \div A_{ILL}$ (mW/cm^2)
- $ILL_{BLU} = [OP_{BLU\text{-}RATIO} \times Q_{INCIDENT}] \div A_{ILL}$ (W/cm^2)
- $ILL_{BLU1} = [OP_{BLU1\text{-}RATIO} \times Q_{INCIDENT}] \div A_{ILL}$ (W/cm^2)

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- $A_{ILL} = A_{ARRAY} \div (1 - OV_{ILL})$ (cm^2)

where:

- ILL_{UV} = UV illumination power density on the DMD (mW/cm^2)
- ILL_{VIS} = VIS illumination power density on the DMD (W/cm^2)
- ILL_{IR} = IR illumination power density on the DMD (mW/cm^2)
- ILL_{BLU} = BLU illumination power density on the DMD (W/cm^2)
- ILL_{BLU1} = BLU1 illumination power density on the DMD (W/cm^2)
- A_{ILL} = illumination area on the DMD (cm^2)
- $Q_{INCIDENT}$ = total incident optical power on DMD (W) (measured)
- A_{ARRAY} = area of the array (cm^2) (data sheet)
- OV_{ILL} = percent of total illumination on the DMD outside the array (%) (optical model)
- $OP_{UV\text{-}RATIO}$ = ratio of the optical power for wavelengths <410nm to the total optical power in the illumination spectrum (spectral measurement)
- $OP_{VIS\text{-}RATIO}$ = ratio of the optical power for wavelengths ≥410 and ≤800nm to the total optical power in the illumination spectrum (spectral measurement)
- $OP_{IR\text{-}RATIO}$ = ratio of the optical power for wavelengths >800nm to the total optical power in the illumination spectrum (spectral measurement)
- $OP_{BLU\text{-}RATIO}$ = ratio of the optical power for wavelengths ≥410 and ≤475nm to the total optical power in the illumination spectrum (spectral measurement)
- $OP_{BLU1\text{-}RATIO}$ = ratio of the optical power for wavelengths ≥410 and ≤445nm to the total optical power in the illumination spectrum (spectral measurement)

The illumination area varies and depends on the illumination overfill. The total illumination area on the DMD is the array area and overfill area around the array. The optical model is used to determine the percent of the total illumination on the DMD that is outside the array (OV_{ILL}) and the percent of the total illumination that is on the active array. From these values the illumination area (A_{ILL}) is calculated. The illumination is assumed to be uniform across the entire array.

From the measured illumination spectrum, the ratio of the optical power in the wavelength bands of interest to the total optical power is calculated.

Sample calculation:

$Q_{INCIDENT}$ = 2.90W (measured)

A_{ARRAY} = (0.5184 × 0.2916) = 0.1512cm^2 (data sheet)

OV_{ILL} = 16.3% (optical model)

$OP_{UV\text{-}RATIO}$ = 0.00021 (spectral measurement)

$OP_{VIS\text{-}RATIO}$ = 0.99977 (spectral measurement)

$OP_{IR\text{-}RATIO}$ = 0.00002 (spectral measurement)

$OP_{BLU\text{-}RATIO}$ = 0.28100 (spectral measurement)

$OP_{BLU1\text{-}RATIO}$ = 0.03200 (spectral measurement)

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A_{ILL} = 0.1512 ÷ (1 - 0.163) = 0.1806cm^2

ILL_{UV} = [0.00021 × 2.90W] × 1000 ÷ 0.1806cm^2 = 3.372mW/cm^2

ILL_{VIS} = [0.99977 × 2.90W] ÷ 0.1806cm^2 = 16.05W/cm^2

ILL_{IR} = [0.00002 × 2.90W] × 1000 ÷ 0.1806cm^2 = 0.321mW/cm^2

ILL_{BLU} = [0.28100 × 2.90W] ÷ 0.1806cm^2 = 4.51W/cm^2

ILL_{BLU1} = [0.03200 × 2.90W] ÷ 0.1806cm^2 = 0.51W/cm^2

6.8 Micromirror Landed-On/Landed-Off Duty Cycle

6.8.1 Definition of Micromirror Landed-On/Landed-Off Duty Cycle

The micromirror landed-on/landed-off duty cycle (landed duty cycle) denotes the amount of time (as a percentage) that an individual micromirror is landed in the ON state versus the amount of time the same micromirror is landed in the OFF state.

As an example, a landed duty cycle of 75/25 indicates that the referenced pixel is in the ON state 75% of the time and in the OFF state 25% of the time, whereas 25/75 would indicate that the pixel is in the ON state 25% of the time. Likewise, 50/50 indicates that the pixel is ON 50% of the time and OFF 50% of the time.

Note that when assessing the landed duty cycle, the time spent switching from one state (ON or OFF) to the other state (OFF or ON) is considered negligible and is thus ignored.

Since a micromirror can only be landed in one state or the other (ON or OFF), the two numbers (percentages) nominally add to 100.

6.8.2 Landed Duty Cycle and Useful Life of the DMD

Knowing the long-term average landed duty cycle (of the end product or application) is important because subjecting all (or a portion) of the DMD's micromirror array to an asymmetric landed duty cycle for a prolonged period of time can reduce the DMD's usable life.

Note that it is the symmetry/asymmetry of the landed duty cycle that is of relevance. The symmetry of the landed duty cycle is determined by how close the two numbers (percentages) are to being equal. For example, a landed duty cycle of 50/50 is perfectly symmetrical whereas a landed duty cycle of 100/0 or 0/100 is perfectly asymmetrical.

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6.8.3 Landed Duty Cycle and Operational DMD Temperature

Operational DMD temperature and landed duty cycle interact to affect the DMD's usable life. This is quantified in the derating curve shown in 図 5-1. The importance of this curve is that:

- All points along this curve represent the same usable life.
- All points above this curve represent lower usable life (and the further away from the curve, the lower the usable life).
- All points below this curve represent higher usable life (and the further away from the curve, the higher the usable life).

This curve specifies the maximum operating DMD temperature that the DMD should be operated at for a given long-term average landed duty cycle.

6.8.4 Estimating the Long-Term Average Landed Duty Cycle of a Product or Application

During a given period of time, the nominal landed duty cycle of a given pixel is determined by the image content being displayed by that pixel.

For example, in the simplest case, when displaying pure white on a given pixel for a given time period, that pixel will experience very close to a 100/0 landed duty cycle during that time period. Likewise, when displaying pure black, the pixel will experience very close to a 0/100 landed duty cycle.

Between the two extremes (ignoring for the moment color and any image processing that may be applied to an incoming image), the landed duty cycle tracks one-to-one with the grayscale value, as shown in 表 6-1.

表 6-1. Grayscale Value and Landed Duty Cycle

Grayscale Value	Nominal Landed Duty Cycle
0%	0/100
10%	10/90
20%	20/80
30%	30/70
40%	40/60
50%	50/50
60%	60/40
70%	70/30
80%	80/20
90%	90/10
100%	100/0

Accounting for color rendition (but still ignoring image processing) requires knowing both the color scale value (from 0% to 100%) for each constituent primary color (red, green, and/or blue) for the given pixel as well as the color cycle time for each primary color, where "color cycle time" is the total percentage of the frame time that a given primary must be displayed to achieve the desired white point.

During a given period of time, the nominal landed duty cycle of a given pixel can be calculated as follows:

$$\text{Landed Duty Cycle} = (\text{Red_Cycle_\%} \times \text{Red_Scale_Value}) + (\text{Green_Cycle_\%} \times \text{Green_Scale_Value}) + (\text{Blue_Cycle_\%} \times \text{Blue_Scale_Value}) \quad (1)$$

where

Red_Cycle_%, Green_Cycle_%, and Blue_Cycle_% represent the percentage of the frame time that red, green, and blue are displayed (respectively) to achieve the desired white point.

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For example, assuming that the red, green and blue color cycle times are 50%, 20%, and 30% respectively (in order to achieve the desired white point), then the nominal landed duty cycle for various combinations of red, green, blue color intensities would be as shown in 表 6-2.

表 6-2. Example Landed Duty Cycle for Full-Color Pixels

Red Cycle Percentage	Green Cycle Percentage	Blue Cycle Percentage
50%	20%	30%

Red Scale Value	Green Scale Value	Blue Scale Value	Nominal Landed Duty Cycle
0%	0%	0%	0/100
100%	0%	0%	50/50
0%	100%	0%	20/80
0%	0%	100%	30/70
12%	0%	0%	6/94
0%	35%	0%	7/93
0%	0%	60%	18/82
100%	100%	0%	70/30
0%	100%	100%	50/50
100%	0%	100%	80/20
12%	35%	0%	13/87
0%	35%	60%	25/75
12%	0%	60%	24/76
100%	100%	100%	100/0

The last factor to account for in estimating the landed duty cycle is any applied image processing. Within the DLP controller DLPC3434ZVB, the three functions which influence the actual landed duty cycle are gamma, IntelliBright™, and bitplane sequencing rules.

Gamma is a power function of the form Output_Level = A × Input_Level^{Gamma}, where A is a scaling factor that is typically set to 1.

In the DLPC3434ZVB controller, gamma is applied to the incoming image data on a pixel-by-pixel basis. A typical gamma factor is 2.2, which transforms the incoming data as shown in 図 6-2.

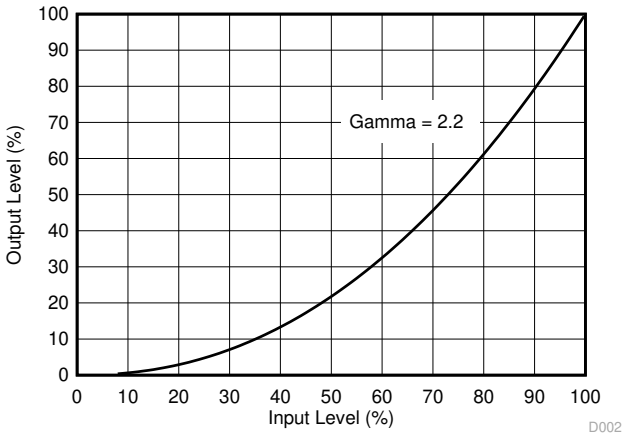


図 6-2. Example of Gamma = 2.2

For example, from 図 6-2, if the grayscale value of a given input pixel is 40% (before gamma is applied), then the grayscale value is 13% after gamma is applied. This reduction indicates that gamma has a direct impact on the displayed gray scale level of a pixel, and it also has a direct impact on the landed duty cycle of a pixel.

The IntelliBright algorithm for content-adaptive illumination control (CAIC) and local area brightness boost (LABB) also apply transform functions on the grayscale level of each pixel.

But while the amount of gamma applied to every pixel of every frame is constant (the exponent, gamma, is constant), CAIC and LABB are both adaptive functions that can apply different amounts of either boost or compression to every pixel of every frame.

Give consideration to any image processing which occurs before the DLPC34x6 controller.

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7 Application and Implementation

注

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7.1 Application Information

The DMDs are spatial light modulators that reflect incoming light from an illumination source to one of two directions, with the primary direction being into a projection or collection optic. Each application is derived primarily from the optical architecture of the system and the format of the data coming into the DLPC34x6 controller. The new high-tilt pixel in the side-illuminated DMD increases brightness performance and enables a smaller system footprint for thickness-constrained applications. Applications of interest include projection technology embedded in display devices such as ultra low-power battery operated mobile accessory projectors, phones, tablets, ultra mobile low end smart TVs, and virtual assistants.

The PMIC/LED driver strictly controls the DMD power-up and power-down sequencing. Refer to セクション 9 for power-up and power-down specifications. To ensure reliable operation, the DMD must always be used with the DLPC34x6 display controller and either the DLPA2000, DLPA2005, DLPA3000 , and DLPA3005PMIC/LED driver.

7.2 Typical Application

A common application when using a DLP230NP/NPSE DMD and a DLPC34x6 is for creating a Pico projector that can be used as an accessory to a smartphone, tablet, or laptop. The DLPC34x6 controller in the Pico projector receives images from a multimedia front end within the product as shown in 図 7-1.

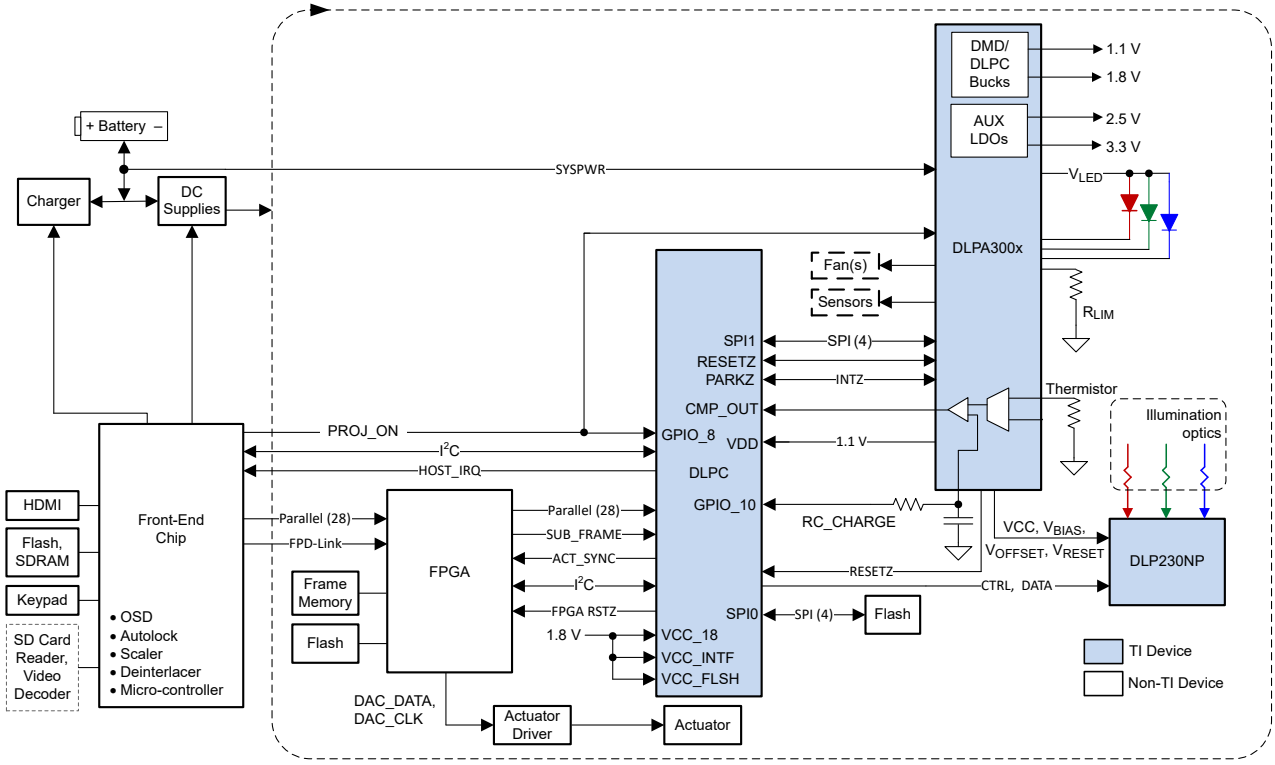


図 7-1. Typical Application Diagram

7.2.1 Design Requirements

A Pico projector is created by using a DLP chipset with a DLP230NP/NPSE (.23 1080p) digital micromirror device (DMD), a DLPC34x6 controller, a XC7Z020-1CLG484|4493 FPGA or XC7S50-2CSGA324C4493 FPGA, and a DLPAxxxx PMIC/LED driver. The DLPC34x6 controller performs the digital image processing, the DLPA2000/2005/3000/3005 provides the needed analog functions for the projector, and the DLP230NP/NPSE DMD is the display device for producing the projected image.

In addition to the three DLP chips in the chipset, other chips are needed. At a minimum, a flash part is needed to store the DLPC34x6 controller software.

The illumination light that is applied to the DMD is typically from red, green, and blue LEDs. These are often contained in three separate packages, but sometimes more than one color of LED die may be in the same package to reduce the overall size of the Pico projector.

Power to the entire Pico projector can be controlled with a single signal called PROJ_ON. When PROJ_ON is high, the projector turns on and begins displaying images. When PROJ_ON is set low, the projector turns off and draws microamps of current on SYSPWR. When PROJ_ON is set low, the 1.8V supply can remain at 1.8V and used by other non-projector sections of the product. If PROJ_ON is low, the PMIC/LED driver does not draw current on the 1.8V supply.

7.2.2 Detailed Design Procedure

For connecting the DLPC34x6 controller, the DLPAxxxx PMIC/LED driver, and the (.23 1080p) DMD see the reference design schematic. The reference design describes an application on which a very small circuit board

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can be used. An example small board layout is included in the reference design database. Layout guidelines should be followed to achieve a reliable projector.

An optical OEM that specializes in designing optics for DLP projectors typically supplies the optical engine including mounted LED packages and mounted DMD.

7.2.3 Application Curve

As the LED currents that are driven time-sequentially through the red, green, and blue LEDs are increased, the brightness of the projector increases. This increase is somewhat non-linear, and the curve for typical white screen lumens changes with LED currents is as shown in 図 7-2. For the LED currents shown, it is assumed that the same current amplitude is applied to the red, green, and blue LEDs.

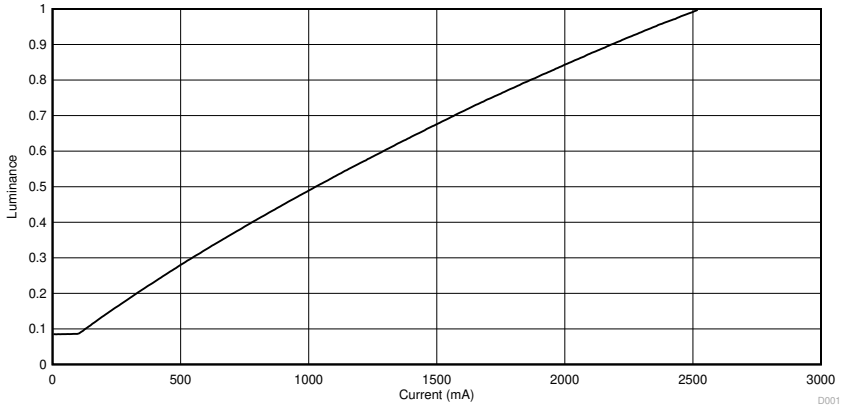


図 7-2. Luminance vs LED Current

8 Layout

8.1 Layout Guidelines

The DMD connects to a PCB or a flex circuit using an interposer. For additional layout guidelines regarding length matching, and impedance, see the DLPC34x6 controller data sheet. For a detailed layout example refer to the layout design files. Some layout guidelines for routing to the DMD are:

- Match lengths for the LS_WDATA and LS_CLK signals.
- Minimize vias, layer changes, and turns for the HS bus signals. Refer to 図 8-1.
- Minimum of two 100nF (25V) capacitors—one close to V_{BIAS} pin. Capacitors C4 and C8 in 図 8-1.
- Minimum of two 100nF (25V) capacitors—one close to each V_{RST} pin. Capacitors C3 and C7 in 図 8-1.
- Minimum of two 220nF (25V) capacitors—one close to each V_{OFS} pin. Capacitors C5 and C6 in 図 8-1.
- Minimum of four 100nF (6.3V) capacitors—two close to each side of the DMD. Capacitors C1, C2, C9 and C10 in 図 8-1.

8.2 Layout Example

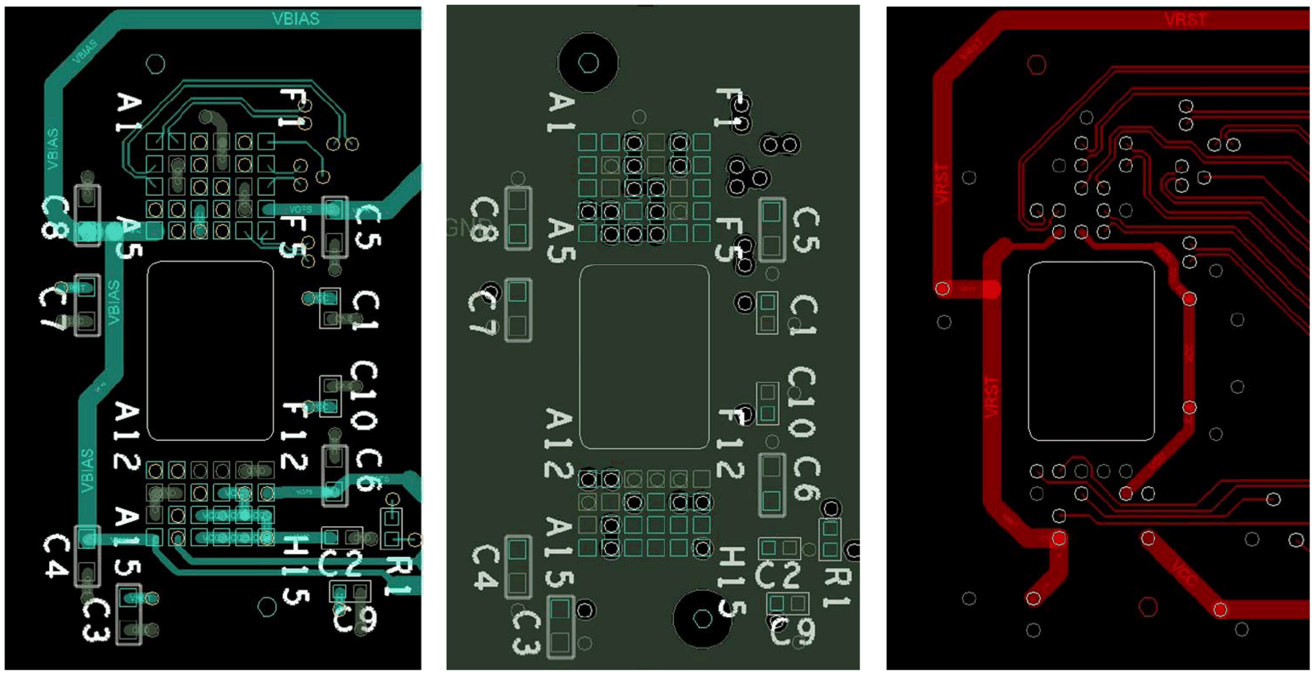


図 8-1. Power Supply Connections

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9 Power Supply Recommendations

The following power supplies are all required to operate the DMD: V_{DD}, V_{DDI}, V_{OFFSET}, V_{BIAS}, and V_{RESET}. All V_{SS} connections are also required. DMD power-up and power-down sequencing is strictly controlled by the DLPA2000/2005/3000 devices.

> **注意**
>
> For reliable operation of the DMD, the following power supply sequencing requirements must be followed. Failure to adhere to the prescribed power-up and power-down procedures may affect device reliability.
>
> V_{DD}, V_{DDI}, V_{OFFSET}, V_{BIAS}, and V_{RESET} power supplies have to be coordinated during power-up and power-down operations. Failure to meet any of the specified requirements results in a significant reduction in the DMD reliability and lifetime. Refer to 図 9-2. V_{SS} must also be connected.

9.1 Power Supply Power-Up Procedure

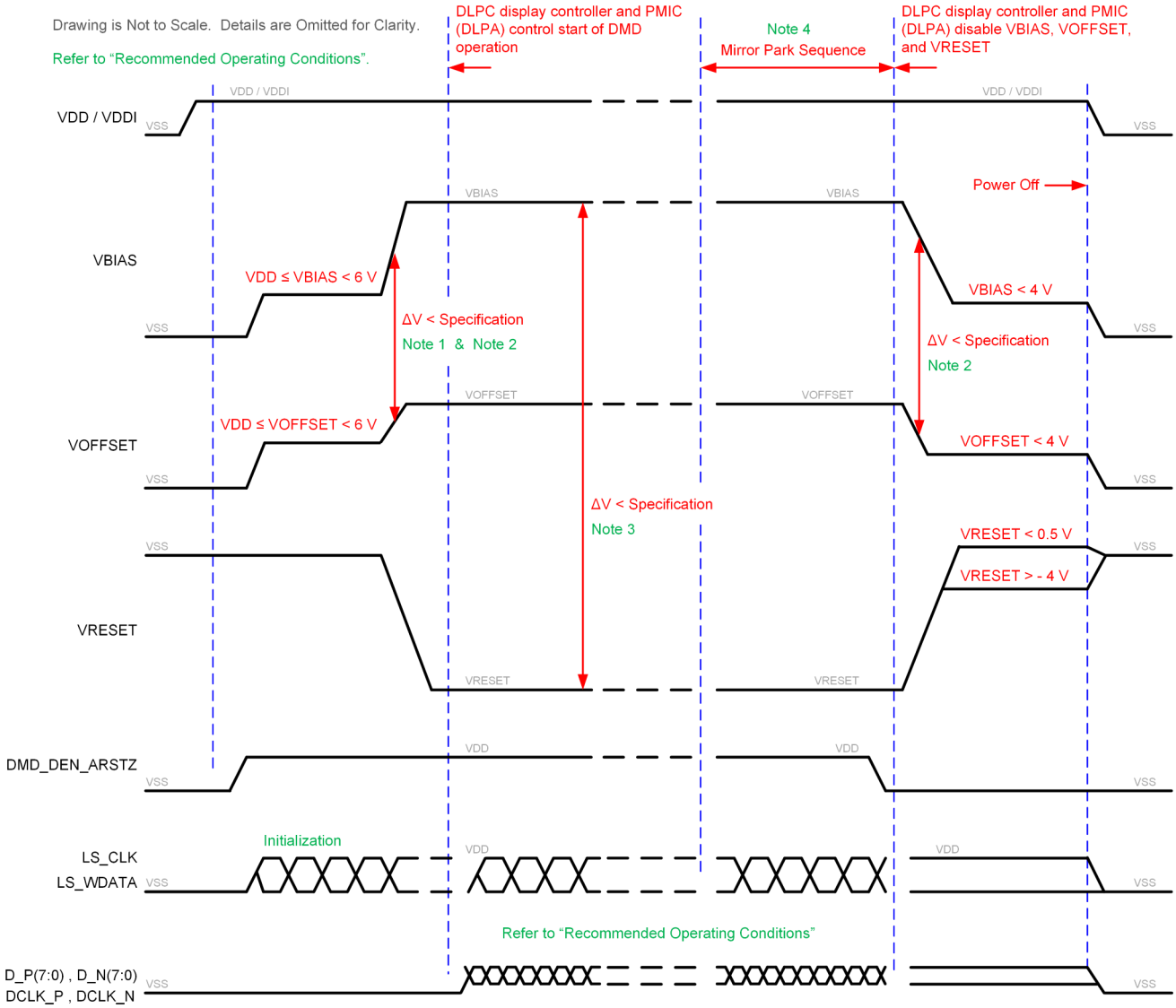
- During power-up, V_{DD} and V_{DDI} must always start and settle before V_{OFFSET}, V_{BIAS}, and V_{RESET} voltages are applied to the DMD.
- During power-up, it is a strict requirement that the delta between V_{BIAS} and V_{OFFSET} must be within the specified limit shown in セクション 5.4. Refer to 図 9-2 for power-up delay requirements.
- During power-up, the DMD's LPSDR input pins shall not be driven high until after V_{DD} and V_{DDI} have settled at operating voltage.
- During power-up, there is no requirement for the relative timing of V_{RESET} with respect to V_{OFFSET} and V_{BIAS}. Power supply slew rates during power-up are flexible, provided that the transient voltage levels follow the requirements listed previously and in 図 9-1.

9.2 Power Supply Power-Down Procedure

- The power-down sequence is the reverse order of the previous power-up sequence. V_{DD} and V_{DDI} must be supplied until after V_{BIAS}, V_{RESET}, and V_{OFFSET} are discharged to within 4V of ground.
- During power-down, it is not mandatory to stop driving V_{BIAS} prior to V_{OFFSET}, but it is a strict requirement that the delta between V_{BIAS} and V_{OFFSET} must be within the specified limit shown in セクション 5.4 (Refer to Note 2 for 図 9-1).
- During power-down, the DMD's LPSDR input pins must be less than V_{DDI}, the specified limit shown in セクション 5.4.
- During power-down, there is no requirement for the relative timing of V_{RESET} with respect to V_{OFFSET} and V_{BIAS}.
- Power supply slew rates during power-down are flexible, provided that the transient voltage levels follow the requirements listed previously and in 図 9-1.

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9.3 Power Supply Sequencing Requirements



A. Refer to 表 9-1 and 図 9-2 for critical power-up sequence delay requirements.

B. To prevent excess current, the supply voltage delta $|V_{BIAS} – V_{OFFSET}|$ must be less than specified in セクション 5.4. OEMs may find that the most reliable way to ensure this is to power V_{OFFSET} prior to V_{BIAS} during power-up and to remove V_{BIAS} prior to V_{OFFSET} during power-down. Refer to 表 9-1 and 図 9-2 for power-up delay requirements.

C. To prevent excess current, the supply voltage delta $|V_{BIAS} – V_{RESET}|$ must be less than the specified limit shown in セクション 5.4.

D. When system power is interrupted, the DLPA2000/2005/3000/3005 initiates hardware power-down that disables V_{BIAS}, V_{RESET}, and V_{OFFSET} after the micromirror park sequence.

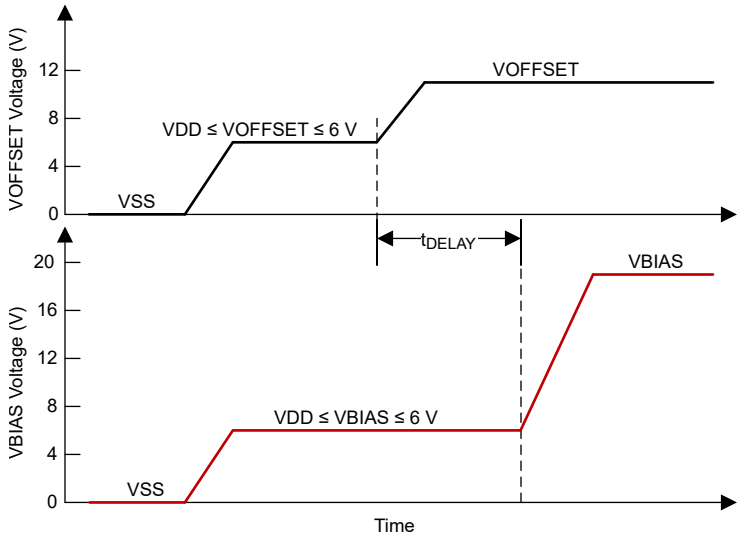
E. Drawing is not to scale and details are omitted for clarity.

図 9-1. Power Supply Sequencing Requirements (Power Up and Power Down)

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表 9-1. Power-Up Sequence Delay Requirement

PARAMETER		MIN	MAX	UNIT
t_{DELAY}	Delay requirement from V_{OFFSET} power up to V_{BIAS} power up	2		ms
V_{OFFSET}	Supply voltage level at beginning of power-up sequence delay (see 図 9-2)		6	V
V_{BIAS}	Supply voltage level at end of power-up sequence delay (see 図 9-2)		6	V



Refer to 表 9-1 for V_{OFFSET} and V_{BIAS} supply voltage levels during power-up sequence delay.

図 9-2. Power-Up Sequence Delay Requirement

10 Device and Documentation Support

10.1 Device Support

10.1.1 サード・パーティ製品に関する免責事項

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10.1.2 Device Nomenclature

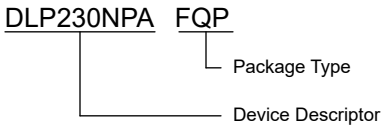


図 10-1. Part Number Description

10.1.3 Device Markings

The device marking includes the legible character string GHJJJJK. DLP230NPAFQP is the device marking.

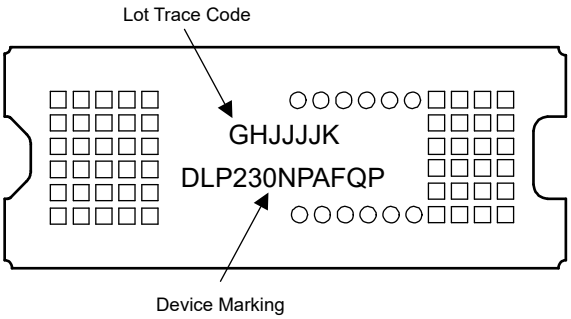


図 10-2. DMD Marking

10.2 Chipset Resources

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

表 10-1. Chipset Resources

CHIP SET COMPONENTS	PRODUCT FOLDER	ORDERING and QUALITY	TECHNICAL DOCUMENTATION	DESIGN and DEVELOPMENT	SUPPORT and TRAINING
DLP230NP/NPSE	Click here	Click here	Click here	Click here	Click here
DLPA2000	Click here	Click here	Click here	Click here	Click here
DLPA2005	Click here	Click here	Click here	Click here	Click here
DLPA3000	Click here	Click here	Click here	Click here	Click here
DLPA3005	Click here	Click here	Click here	Click here	Click here
DLPC34x6	Click here	Click here	Click here	Click here	Click here

10.3 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

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10.7 用語集

テキサス・インスツルメンツ用語集　この用語集には、用語や略語の一覧および定義が記載されています。

11 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

Changes from Revision F (June 2023) to Revision G (October 2024)	Page
• Updated simplified image diagram	30
• Added new supported FPGA information	30

Changes from Revision E (April 2023) to Revision F (June 2023)	Page
• 「概要」を更新	1
• Added "ILLUMINATION" to the *Recommended Operating Conditions*	7
• Updated *Micromirror Array Temperature Calculation*	22

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12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DLP230NPAFQP	Active	Production	CLGA (FQP) | 54	140 | JEDEC TRAY (5+1)	Yes	NIAU	N/A for Pkg Type	0 to 70	
DLP230NPAFQP.A	Active	Production	CLGA (FQP) | 54	140 | JEDEC TRAY (5+1)	Yes	NIAU	N/A for Pkg Type	0 to 70	
DLP230NPAFQP.B	Active	Production	CLGA (FQP) | 54	140 | JEDEC TRAY (5+1)	Yes	NIAU	N/A for Pkg Type	0 to 70	

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

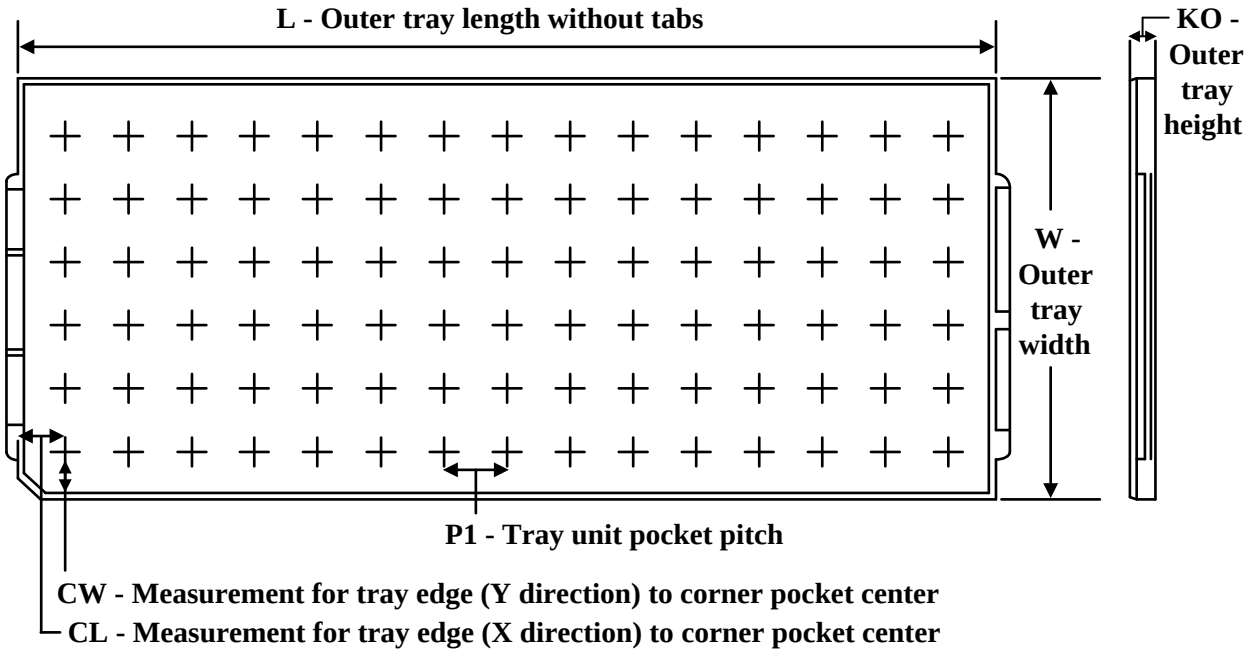
(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TRAY



Chamfer on Tray corner indicates Pin 1 orientation of packed units.

*All dimensions are nominal

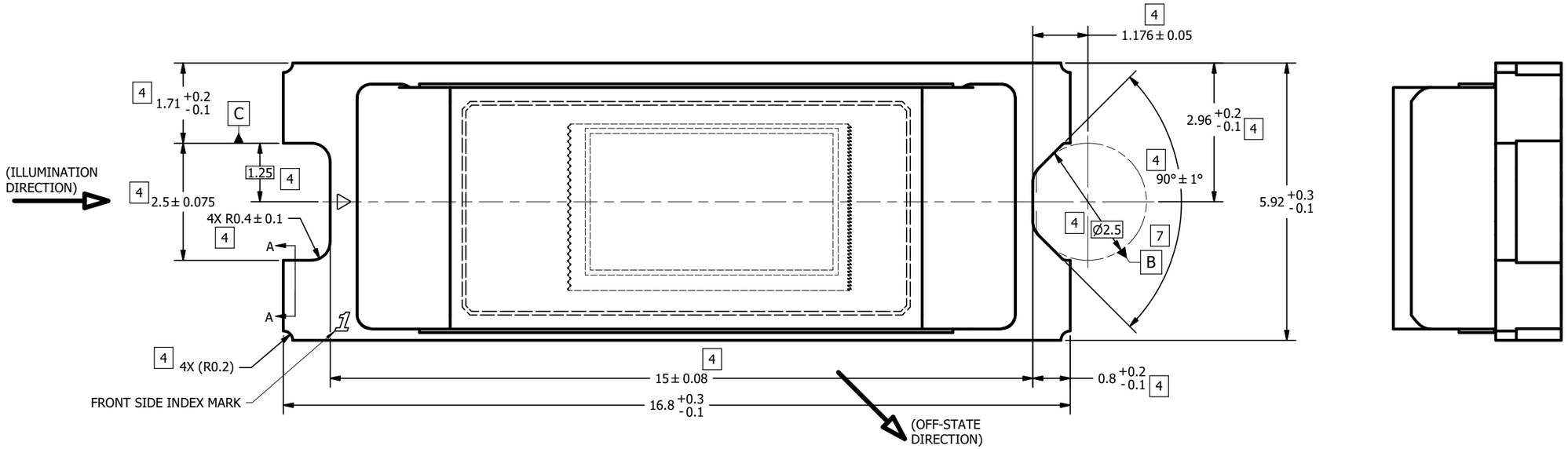
Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	K0 (µm)	P1 (mm)	CL (mm)	CW (mm)
DLP230NPAFQP	FQP	CLGA	54	140	10 x 14	150	315	135.9	12190	21.9	15.15	16.2
DLP230NPAFQP.A	FQP	CLGA	54	140	10 x 14	150	315	135.9	12190	21.9	15.15	16.2
DLP230NPAFQP.B	FQP	CLGA	54	140	10 x 14	150	315	135.9	12190	21.9	15.15	16.2

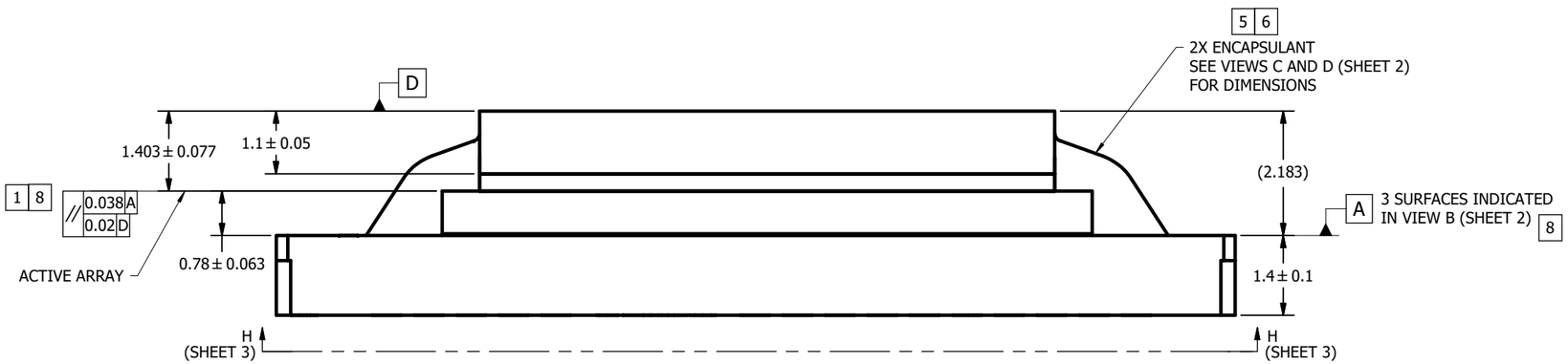
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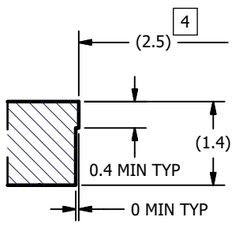
REVISIONS			
REV	DESCRIPTION	DATE	BY
A	ECO 2168534: INITIAL RELEASE	9/5/2017	BMH
B	ECO 2168970: CORRECT SUBSTRATE THICKNESS TOL; ENLARGE APERTURE SLIGHTLY	9/15/17	BMH
C	ECO 2186788: ADD APERTURE SLOT PICTORIALLY	4/7/2020	BMH

NOTES UNLESS OTHERWISE SPECIFIED:

1. DIE PARALLELISM TOLERANCE APPLIES TO DMD ACTIVE ARRAY ONLY.
2. ROTATION ANGLE OF DMD ACTIVE ARRAY IS A REFINEMENT OF THE LOCATION TOLERANCE AND HAS A MAXIMUM ALLOWED VALUE OF 0.6 DEGREES.
3. BOUNDARY MIRRORS SURROUNDING THE DMD ACTIVE ARRAY.
4. NOTCH DIMENSIONS ARE DEFINED BY UPPERMOST LAYERS OF CERAMIC, AS SHOWN IN SECTION A-A.
5. ENCAPSULANT TO BE CONTAINED WITHIN DIMENSIONS SHOWN IN VIEW C (SHEET 2). NO ENCAPSULANT IS ALLOWED ON TOP OF THE WINDOW.
6. ENCAPSULANT NOT TO EXCEED THE HEIGHT OF THE WINDOW.
7. DATUM B IS DEFINED BY A DIA. 2.5 PIN, WITH A FLAT ON THE SIDE FACING TOWARD THE CENTER OF THE ACTIVE ARRAY, AS SHOWN IN VIEW B (SHEET 2).
8. WHILE ONLY THE THREE DATUM A TARGET AREAS A1, A2, AND A3 ARE USED FOR MEASUREMENT, ALL 4 CORNERS SHOULD BE CONTACTED, INCLUDING E1, TO SUPPORT MECHANICAL LOADS.







SECTION A-A
(ROTATED 90°)
SCALE 20 : 1

	0314DA
NEXT ASSY	USED ON
APPLICATION	

THIRD ANGLE PROJECTION

UNLESS OTHERWISE SPECIFIED
- DIMENSIONS ARE IN MILLIMETERS
- TOLERANCES:
  - ANGLES ± 1°
  - 2 PLACE DECIMALS ± 0.25
  - 1 PLACE DECIMALS ± 0.50
- ~~DIMENSIONAL LIMITS APPLY BEFORE PROCESSES~~
- INTERPRET DIMENSIONS IN ACCORDANCE WITH ASME Y14.5M-1994
- ~~REMOVE ALL BURRS AND SHARP EDGES~~
- PARENTHETICAL INFORMATION FOR REFERENCE ONLY

		DATE
DRAWN	B. HASKETT	9/5/2017
ENGINEER	B. HASKETT	9/5/2017
QA/CE	P. KONRAD	9/10/2017
CM	J. GRIMMETT	9/6/2017
	M. DORAK	9/5/2017
APPROVED	R. LONG	9/11/2017

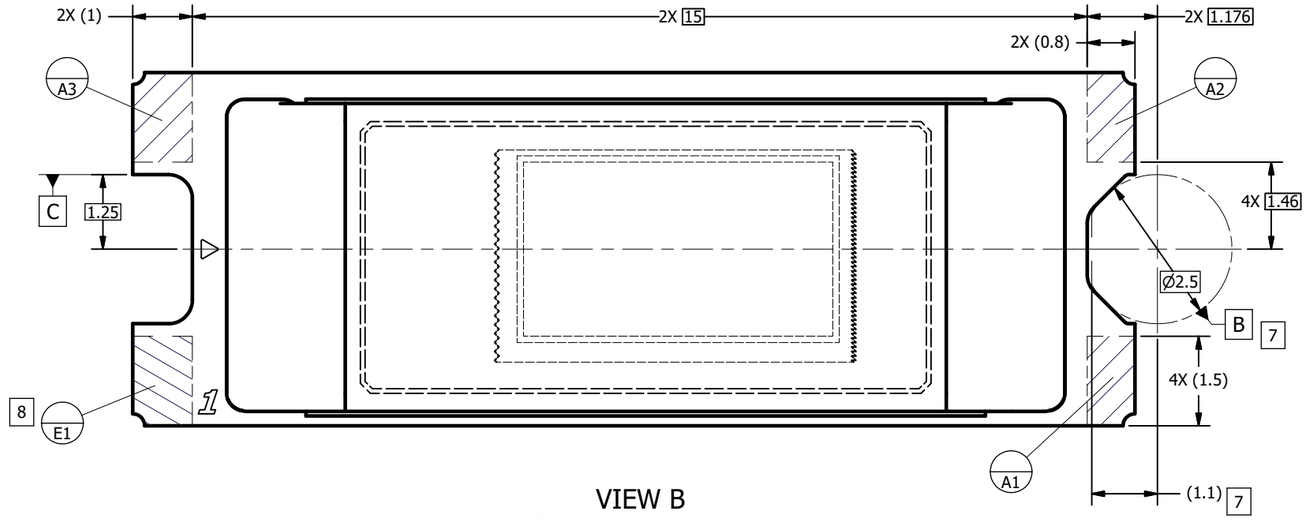
TEXAS INSTRUMENTS
Dallas Texas

TITLE: ICD, MECHANICAL, DMD, .23 TRP SERIES 246 (FQP PACKAGE)

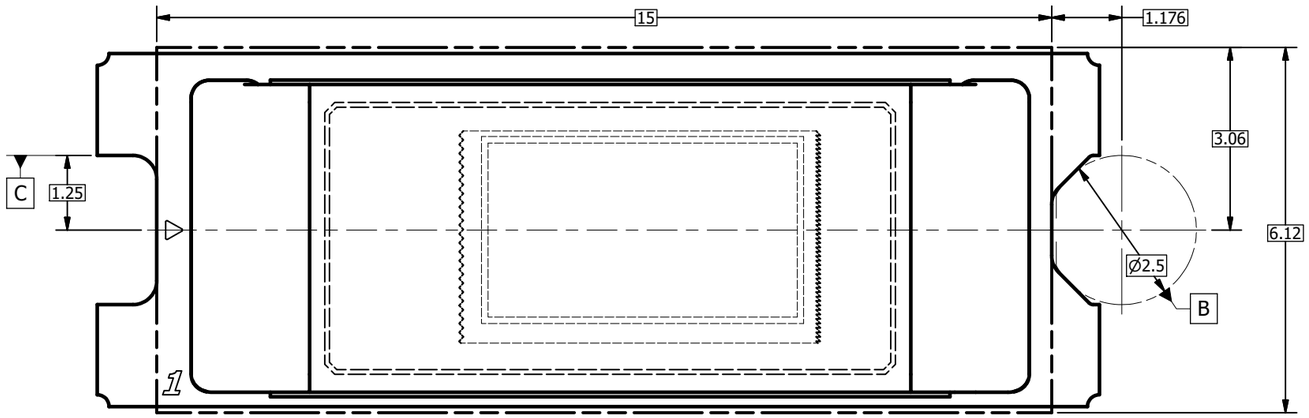
SIZE	DWG NO	REV
D	2515699	C

SCALE 20:1 SHEET 1 OF 3

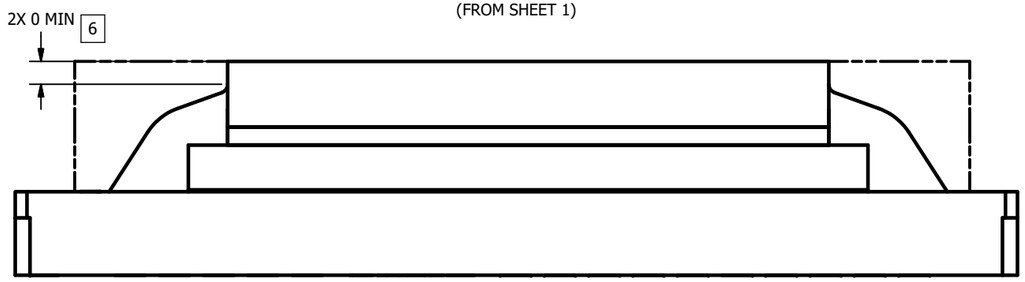
INV11-2006a



VIEW B
DATUMS A, B, C, AND E
(FROM SHEET 1)



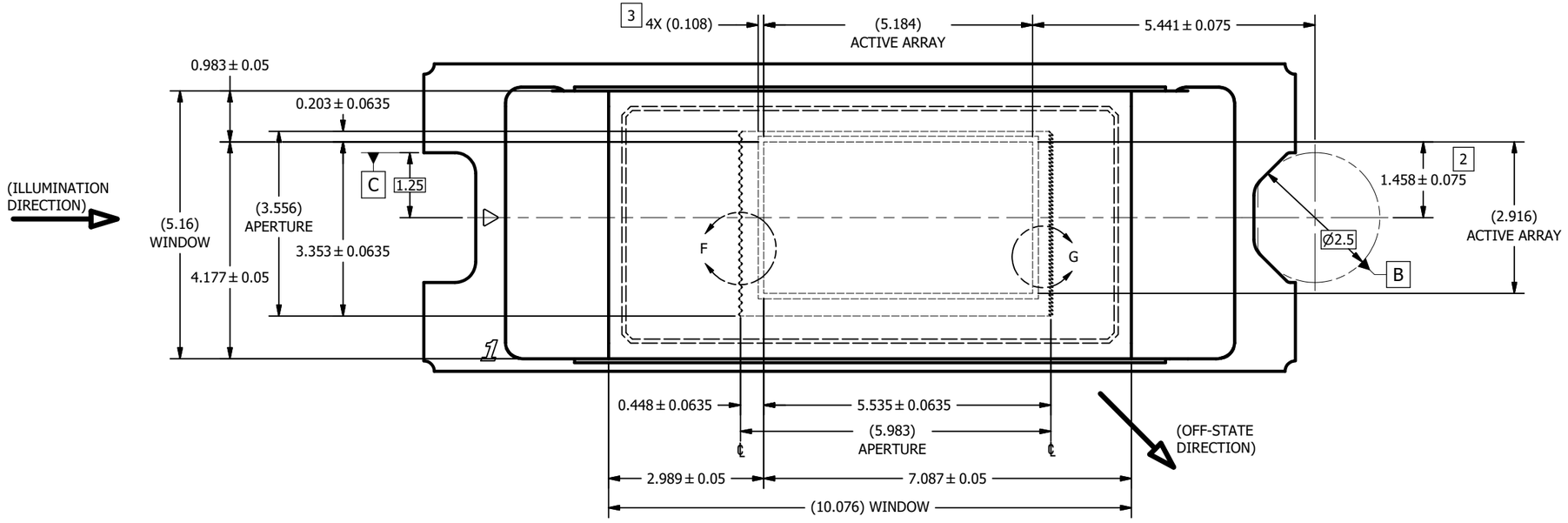
VIEW C 5
ENCAPSULANT MAXIMUM X/Y DIMENSIONS
(FROM SHEET 1)



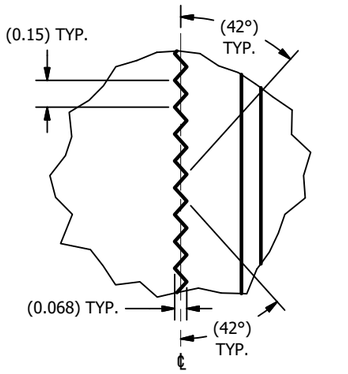
VIEW D
ENCAPSULANT MAXIMUM HEIGHT

TEXAS INSTRUMENTS Dallas Texas	DRAWN B. HASKETT	DATE 9/5/2017	SIZE D	DWG NO 2515699 REV C
			SCALE	SHEET 2 OF 3

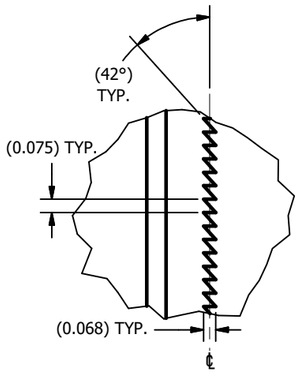
INV11-2006a



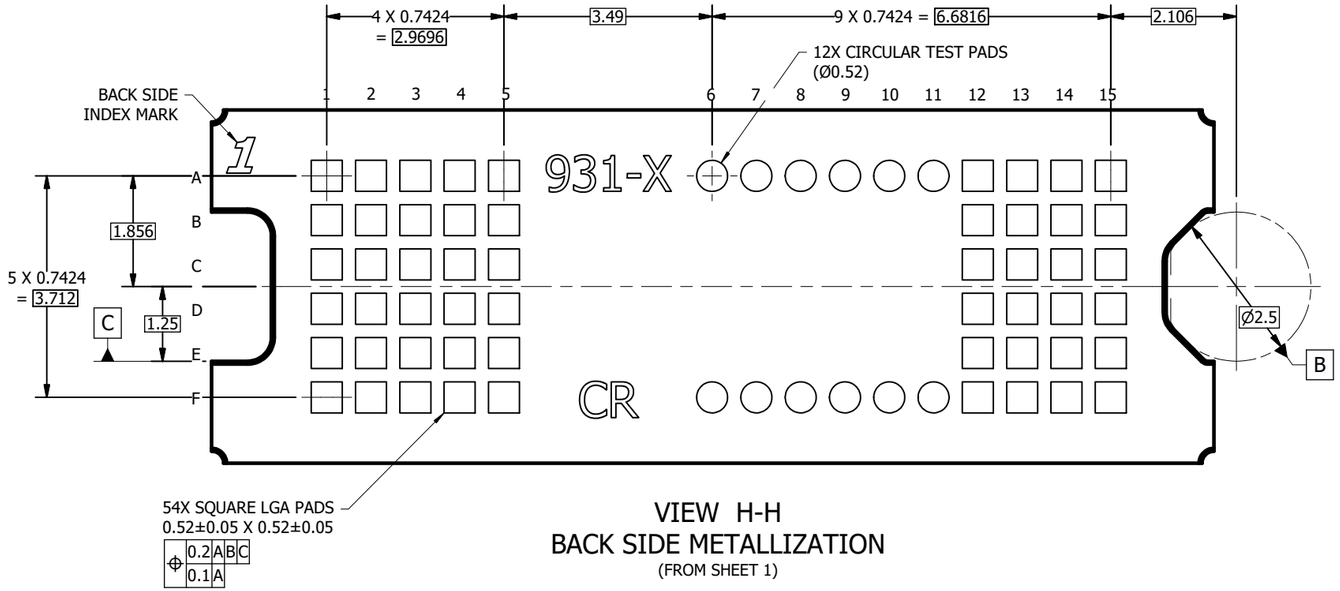
VIEW E
WINDOW AND ACTIVE ARRAY
(FROM SHEET 1)



DETAIL F
APERTURE LEFT EDGE
SCALE 60 : 1



DETAIL G
APERTURE RIGHT EDGE
SCALE 60 : 1



VIEW H-H
BACK SIDE METALLIZATION
(FROM SHEET 1)

TEXAS INSTRUMENTS Dallas Texas	DRAWN B. HASKETT	DATE 9/5/2017	SIZE D	DWG NO 2515699	REV C
			SCALE	SHEET 3 OF 3	

INV11-2006a

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